FAIRCHILD SEMICONDUCTOR™

September 1983
Revised January 2005

MM74HC00
Quad 2-Input NAND Gate

General Description

The MM74HC00 NAND gates utilize advanced silicon-gate CMOS technology to achieve operating speeds similar to LS-TTL gates with the low power consumption of standard CMOS integrated circuits. All gates have buffered outputs. All devices have high noise immunity and the ability to drive 10 LS-TTL loads. The 74HC logic family is functionally as well as pin-out compatible with the standard 74LS logic family. All inputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

Features

- Typical propagation delay: 8 ns
- Wide power supply range: 2–6V
- Low quiescent current: 20 μA maximum (74HC Series)
- Low input current: 1 μA maximum
- Fanout of 10 LS-TTL loads

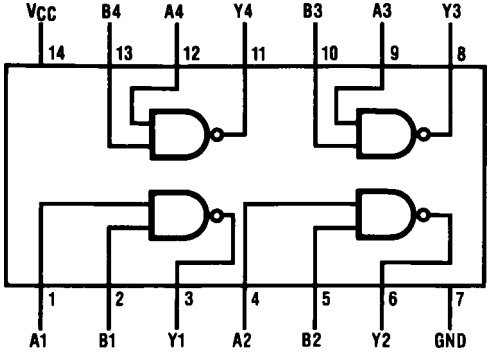
Ordering Code:

Order Number	Package Number	Package Description
MM74HC00M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC00MX_NL	M14A	Pb-Free 14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC00SJ	M14D	Pb-Free 14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC00MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC00MTCX_NL	MTC14	Pb-Free 14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC00N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
MM74HC00N_NL	N14A	Pb-Free 14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.
Pb-Free package per JEDEC J-STD-020B.

Connection Diagram

Pin Assignments for DIP, SOIC, SOP and TSSOP



Top View

Logic Diagram

Absolute Maximum Ratings(Note 1)

(Note 2)

Supply Voltage (V_{CC})	−0.5 to +7.0V
DC Input Voltage (V_{IN})	−1.5 to V_{CC}+1.5V
DC Output Voltage (V_{OUT})	−0.5 to V_{CC}+0.5V
Clamp Diode Current (I_{IK}, I_{OK})	±20 mA
DC Output Current, per pin (I_{OUT})	±25 mA
DC V_{CC} or GND Current, per pin (I_{CC})	±50 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C
Power Dissipation (P_D)	
(Note 3)	600 mW
S.O. Package only	500 mW
Lead Temperature (T_L)	
(Soldering 10 seconds)	260°C

Recommended Operating Conditions

	Min	Max	Units
Supply Voltage (V_{CC})	2	6	V
DC Input or Output Voltage (V_{IN}, V_{OUT})	0	V_{CC}	V
Operating Temperature Range (T_A)	−40	+85	°C
Input Rise or Fall Times			
(t_r, t_f) V_{CC} = 2V		1000	ns
V_{CC} = 4.5V		500	ns
V_{CC} = 6.0V		400	ns

Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: −12 mW/°C from 65°C to 85°C.

DC Electrical Characteristics (Note 4)

Symbol	Parameter	Conditions	V_{CC}	T_A = 25°C	T_A = −40 to 85°C	T_A = −55 to 125°C	Units
				Typ	Guaranteed Limits		
V_{IH}	Minimum HIGH Level Input Voltage		2.0V		1.5	1.5	1.5	V
			4.5V		3.15	3.15	3.15	V
			6.0V		4.2	4.2	4.2	V
V_{IL}	Maximum LOW Level Input Voltage		2.0V		0.5	0.5	0.5	V
			4.5V		1.35	1.35	1.35	V
			6.0V		1.8	1.8	1.8	V
V_{OH}	Minimum HIGH Level Output Voltage	V_{IN} = V_{IH} or V_{IL}						
		$\|I_{OUT}\| \leq$ 20 μA	2.0V	2.0	1.9	1.9	1.9	V
			4.5V	4.5	4.4	4.4	4.4	V
			6.0V	6.0	5.9	5.9	5.9	V
		V_{IN} = V_{IH} or V_{IL}						
		$\|I_{OUT}\| \leq$ 4.0 mA	4.5V	4.2	3.98	3.84	3.7	V
		$\|I_{OUT}\| \leq$ 5.2 mA	6.0V	5.7	5.48	5.34	5.2	V
V_{OL}	Maximum LOW Level Output Voltage	V_{IN} = V_{IH}						
		$\|I_{OUT}\| \leq$ 20 μA	2.0V	0	0.1	0.1	0.1	V
			4.5V	0	0.1	0.1	0.1	V
			6.0V	0	0.1	0.1	0.1	V
		V_{IN} = V_{IH}						
		$\|I_{OUT}\| \leq$ 4.0 mA	4.5V	0.2	0.26	0.33	0.4	V
		$\|I_{OUT}\| \leq$ 5.2 mA	6.0V	0.2	0.26	0.33	0.4	V
I_{IN}	Maximum Input Current	V_{IN} = V_{CC} or GND	6.0V		±0.1	±1.0	±1.0	μA
I_{CC}	Maximum Quiescent Supply Current	V_{IN} = V_{CC} or GND	6.0V		2.0	20	40	μA
		I_{OUT} = 0 μA						

Note 4: For a power supply of 5V ±10% the worst case output voltages (V_{OH}, and V_{OL}) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC} = 5.5V and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current (I_{IN}, I_{CC}, and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0V values should be used.

AC Electrical Characteristics

V_{CC} = 5V, T_A = 25°C, C_L = 15 pF, $t_r = t_f$ = 6 ns

Symbol	Parameter	Conditions	Typ	Guaranteed Limit	Units
t_{PHL}, t_{PLH}	Maximum Propagation Delay		8	15	ns

AC Electrical Characteristics

V_{CC} = 2.0V to 6.0V, C_L = 50 pF, $t_r = t_f$ = 6 ns (unless otherwise specified)

Symbol	Parameter	Conditions	V_{CC}	T_A = 25°C	T_A = −40 to 85°C	T_A = −55 to 125°C	Units
				Typ	Guaranteed Limits		
t_{PHL}, t_{PLH}	Maximum Propagation Delay		2.0V	45	90	113	134	ns
			4.5V	9	18	23	27	ns
			6.0V	8	15	19	23	ns
t_{TLH}, t_{THL}	Maximum Output Rise and Fall Time		2.0V	30	75	95	110	ns
			4.5V	8	15	19	22	ns
			6.0V	7	13	16	19	ns
C_{PD}	Power Dissipation Capacitance (Note 5)	(per gate)		20				pF
C_{IN}	Maximum Input Capacitance			5	10	10	10	pF

Note 5: C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} V_{CC} f + I_{CC}$.

FAIRCHILD SEMICONDUCTOR™

February 1984
Revised January 2005

MM74HCT00
Quad 2 Input NAND Gate

General Description

The MM74HCT00 is a NAND gates fabricated using advanced silicon-gate CMOS technology which provides the inherent benefits of CMOS—low quiescent power and wide power supply range. This device is input and output characteristic and pin-out compatible with standard 74LS logic families. All inputs are protected from static discharge damage by internal diodes to V_{CC} and ground.

MM74HCT devices are intended to interface between TTL and NMOS components and standard CMOS devices. These parts are also plug-in replacements for LS-TTL devices and can be used to reduce power consumption in existing designs.

Features

- TTL, LS pin-out and threshold compatible
- Fast switching: t_{PLH}, t_{PHL}=14 ns (typ)
- Low power: 10 μW at DC
- High fan out, 10 LS-TTL loads

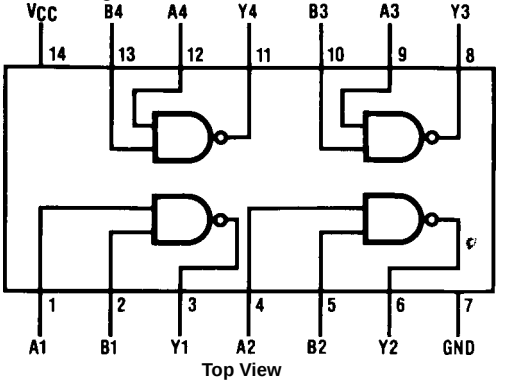
Ordering Code:

Order Number	Package Number	Package Description
MM74HCT00M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HCT00MX_NL	M14A	Pb-Free 14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HCT00SJ	M14D	Pb-Free 14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HCT00MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HCT00MTCX_NL	MTC14	Pb-Free 14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HCT00N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
MM74HCT00N_NL	N14A	Pb-Free 14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.
Pb-Free package per JEDEC J-STD-020B.

Connection Diagram

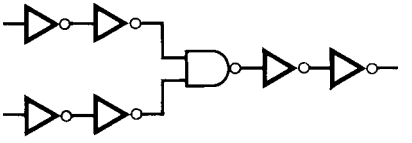
Pin Assignments for DIP, SOIC, SOP and TSSOP



Top View

Logic Diagram

(1 of 4 gates)



Absolute Maximum Ratings(Note 1)

(Note 2)

Supply Voltage (V_{CC})	−0.5 to +7.0V
DC Input Voltage (V_{IN})	−1.5 to V_{CC}+1.5V
DC Output Voltage (V_{OUT})	−0.5 to V_{CC}+0.5V
Clamp Diode Current (I_{IK}, I_{OK})	±20 mA
DC Output Current, per pin (I_{OUT})	±25 mA
DC V_{CC} or GND Current, per pin (I_{CC})	±50 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C
Power Dissipation (P_D)	
(Note 3)	600 mW
S.O. Package only	500 mW
Lead Temperature (T_L)	
(Soldering 10 seconds)	260°C

Recommended Operating Conditions

	Min	Max	Units
Supply Voltage (V_{CC})	4.5	5.5	V
DC Input or Output Voltage (V_{IN}, V_{OUT})	0	V_{CC}	V
Operating Temperature Range (T_A)	−40	+85	°C
Input Rise or Fall Times (t_r, t_f)		500	ns

Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: −12 mW/°C from 65°C to 85°C.

DC Electrical Characteristics

V_{CC} = 5V ± 10% (unless otherwise specified)

Symbol	Parameter	Conditions	T_A = 25°C	T_A = −40 to 85°C	T_A = -55 to 125°C	Units
			Typ	Guaranteed Limits		
V_{IH}	Minimum HIGH Level Input Voltage			2.0	2.0	2.0	V
V_{IL}	Maximum LOW Level Input Voltage			0.8	0.8	0.8	V
V_{OH}	Minimum HIGH Level Output Voltage	V_{IN} = V_{IH} or V_{IL}					
		$\|I_{OUT}\|$ = 20 μA	V_{CC}	V_{CC}−0.1	V_{CC}−0.1	V_{CC}−0.1	V
		$\|I_{OUT}\|$ = 4.0 mA, V_{CC} = 4.5V	4.2	3.98	3.84	3.7	V
		$\|I_{OUT}\|$ = 4.8 mA, V_{CC} = 5.5V	5.2	4.98	4.84	4.7	V
V_{OL}	Maximum LOW Level Voltage	V_{IN} = V_{IH}					
		$\|I_{OUT}\|$ = 20 μA	0	0.1	0.1	0.1	V
		$\|I_{OUT}\|$ = 4.0 mA, V_{CC} = 4.5V	0.2	0.26	0.33	0.4	V
		$\|I_{OUT}\|$ = 4.8 mA, V_{CC} = 5.5V	0.2	0.26	0.33	0.4	V
I_{IN}	Maximum Input Current	V_{IN} = V_{CC} or GND, V_{IH} or V_{IL}		±0.05	±0.5	±1.0	μA
I_{CC}	Maximum Quiescent Supply Current	V_{IN} = V_{CC} or GND, I_{OUT} = 0 μA		1.0	10	40	μA
		V_{IN} = 2.4V or 0.5V (Note 4)	0.18	0.3	0.4	0.5	mA

Note 4: This is measured per input with all other inputs held at V_{CC} or ground.

AC Electrical Characteristics

V_{CC} = 5.0V, $t_r = t_f$ = 6 ns, C_L = 15 pF, T_A = 25°C (unless otherwise noted)

Symbol	Parameter	Conditions	Typ	Guaranteed Limit	Units
t_{PLH}, t_{PHL}	Maximum Propagation Delay		14	18	ns

AC Electrical Characteristics

V_{CC} = 5.0V ±10%, $t_r = t_f$ = 6 ns, C_L = 50 pF (unless otherwise noted)

Symbol	Parameter	Conditions	T_A = 25°C		T_A = −40 to 85°C	T_A = −55 to 125°C	Units
			Typ	Guaranteed Limits			
t_{PLH}, t_{PHL}	Maximum Propagation Delay		18	23	29	35	ns
t_{THL}, t_{TLH}	Maximum Output Rise & Fall Time		8	15	19	22	ns
C_{PD}	Power Dissipation Capacitance	(Note 5)	30				pF
C_{IN}	Input Capacitance		5	10	10	10	pF

Note 5: C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} V_{CC} f + I_{CC}$.

FAIRCHILD SEMICONDUCTOR™

March 1998

DM74LS00
Quad 2-Input NAND Gates

General Description

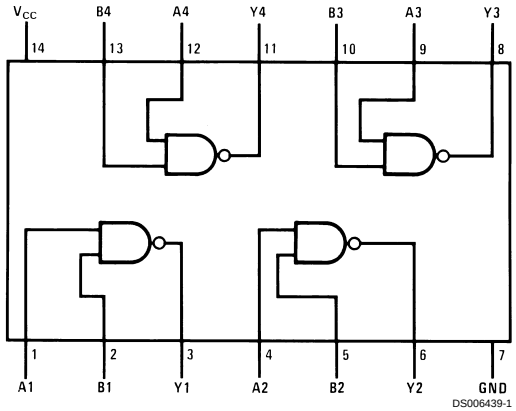
This device contains four independent gates each of which performs the logic NAND function.

Features

- Alternate Military/Aerospace device (54LS00) is available. Contact a Fairchild Semiconductor Sales Office/Distributor for specifications.

Connection Diagram

Dual-In-Line Package



Order Number 54LS00DMQB, 54LS00FMQB, 54LS00LMQB, DM54LS00J, DM54LS00W, DM74LS00M or DM74LS00N
See Package Number E20A, J14A, M14A, N14A or W14B

Function Table

$Y = \overline{AB}$

Inputs		Output
A	B	Y
L	L	H
L	H	H
H	L	H
H	H	L

H = High Logic Level
L = Low Logic Level

Absolute Maximum Ratings (Note 1)

Supply Voltage	7V
Input Voltage	7V
Operating Free Air Temperature Range	
DM54LS and 54LS	−55˚C to +125˚C
DM74LS	0˚C to +70˚C
Storage Temperature Range	−65˚C to +150˚C

Recommended Operating Conditions

Symbol	Parameter	DM54LS00			DM74LS00			Units
		Min	Nom	Max	Min	Nom	Max	
V_{CC}	Supply Voltage	4.5	5	5.5	4.75	5	5.25	V
V_{IH}	High Level Input Voltage	2			2			V
V_{IL}	Low Level Input Voltage			0.7			0.8	V
I_{OH}	High Level Output Current			−0.4			−0.4	mA
I_{OL}	Low Level Output Current			4			8	mA
T_A	Free Air Operating Temperature	−55		125	0		70	˚C

Note 1: *The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.*

Electrical Characteristics

over recommended operating free air temperature range (unless otherwise noted)

Symbol	Parameter	Conditions		Min	Typ (Note 2)	Max	Units
V_I	Input Clamp Voltage	V_{CC} = Min, I_I = −18 mA				−1.5	V
V_{OH}	High Level Output Voltage	V_{CC} = Min, I_{OH} = Max, V_{IL} = Max	DM54	2.5	3.4		V
			DM74	2.7	3.4		
V_{OL}	Low Level Output Voltage	V_{CC} = Min, I_{OL} = Max, V_{IH} = Min	DM54		0.25	0.4	V
			DM74		0.35	0.5	
		I_{OL} = 4 mA, V_{CC} = Min	DM74		0.25	0.4	
I_I	Input Current @ Max Input Voltage	V_{CC} = Max, V_I = 7V				0.1	mA
I_{IH}	High Level Input Current	V_{CC} = Max, V_I = 2.7V				20	µA
I_{IL}	Low Level Input Current	V_{CC} = Max, V_I = 0.4V				−0.36	mA
I_{OS}	Short Circuit Output Current	V_{CC} = Max (Note 3)	DM54	−20		−100	mA
			DM74	−20		−100	
I_{CCH}	Supply Current with Outputs High	V_{CC} = Max			0.8	1.6	mA
I_{CCL}	Supply Current with Outputs Low	V_{CC} = Max			2.4	4.4	mA

Switching Characteristics

at V_{CC} = 5V and T_A = 25˚C

Symbol	Parameter	R_L = 2 kΩ				Units
		C_L = 15 pF		C_L = 50 pF		
		Min	Max	Min	Max	
t_{PLH}	Propagation Delay Time Low to High Level Output	3	10	4	15	ns
t_{PHL}	Propagation Delay Time High to Low Level Output	3	10	4	15	ns

Note 2: All typicals are at V_{CC} = 5V, T_A = 25˚C.

Note 3: Not more than one output should be shorted at a time, and the duration should not exceed one second.

FAIRCHILD SEMICONDUCTOR™

September 1983
Revised January 2005

MM74HC02
Quad 2-Input NOR Gate

General Description

The MM74HC02 NOR gates utilize advanced silicon-gate CMOS technology to achieve operating speeds similar to LS-TTL gates with the low power consumption of standard CMOS integrated circuits. All gates have buffered outputs, providing high noise immunity and the ability to drive 10 LS-TTL loads. The 74HC logic family is functionally as well as pin-out compatible with the standard 74LS logic family. All inputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

Features

- Typical propagation delay: 8 ns
- Wide power supply range: 2–6V
- Low quiescent supply current: 20 μA maximum (74HC Series)
- Low input current: 1 μA maximum
- High output current: 4 mA minimum

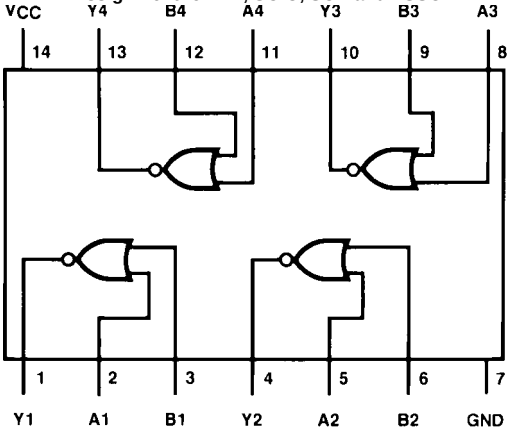
Ordering Code:

Order Number	Package Number	Package Description
MM74HC02M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC02SJ	M14D	Pb-Free 14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC02MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC02MTCX_NL	MTC14	Pb-Free 14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC02N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code. (Tape and Reel not available in N14A.)
Pb-Free package per JEDEC J-STD-020B.

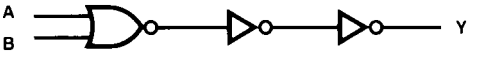
Connection Diagram

Pin Assignment for DIP, SOIC, SOP and TSSOP



Top View

Logic Diagram



Absolute Maximum Ratings(Note 1)

(Note 2)

Supply Voltage (V_{CC})	−0.5 to +7.0V
DC Input Voltage (V_{IN})	−1.5 to V_{CC} +1.5V
DC Output Voltage (V_{OUT})	−0.5 to V_{CC} +0.5V
Clamp Diode Current (I_{IK}, I_{OK})	±20 mA
DC Output Current, per pin (I_{OUT})	±25 mA
DC V_{CC} or GND Current, per pin (I_{CC})	±50 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C
Power Dissipation (P_D)	
(Note 3)	600 mW
S.O. Package only	500 mW
Lead Temperature (T_L)	
(Soldering 10 seconds)	260°C

Recommended Operating Conditions

	Min	Max	Units
Supply Voltage (V_{CC})	2	6	V
DC Input or Output Voltage (V_{IN}, V_{OUT})	0	V_{CC}	V
Operating Temperature Range (T_A)	−40	+125	°C
Input Rise or Fall Times			
(t_r, t_f) V_{CC} = 2.0V		1000	ns
V_{CC} = 4.5V		500	ns
V_{CC} = 6.0V		400	ns

Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: −12 mW/°C from 65°C to 85°C.

DC Electrical Characteristics (Note 4)

Symbol	Parameter	Conditions	V_{CC}	T_A = 25°C	T_A = −40 to 85°C	T_A = −40 to 125°C	Units
				Typ	Guaranteed Limits		
V_{IH}	Minimum HIGH Level Input Voltage		2.0V		1.5	1.5	1.5	V
			4.5V		3.15	3.15	3.15	V
			6.0V		4.2	4.2	4.2	V
V_{IL}	Maximum LOW Level Input Voltage		2.0V		0.5	0.5	0.5	V
			4.5V		1.35	1.35	1.35	V
			6.0V		1.8	1.8	1.8	V
V_{OH}	Minimum HIGH Level Output Voltage	V_{IN} = V_{IL}						
		$\|I_{OUT}\| \le 20$ μA	2.0V	2.0	1.9	1.9	1.9	V
			4.5V	4.5	4.4	4.4	4.4	V
			6.0V	6.0	5.9	5.9	5.9	V
		V_{IN} = V_{IL}						
		$\|I_{OUT}\| \le 4.0$ mA	4.5V	4.2	3.98	3.84	3.7	V
		$\|I_{OUT}\| \le 5.2$ mA	6.0V	5.7	5.48	5.34	5.2	V
V_{OL}	Maximum LOW Level Output Voltage	V_{IN} = V_{IH} or V_{IL}						
		$\|I_{OUT}\| \le 20$ μA	2.0V	0	0.1	0.1	0.1	V
			4.5V	0	0.1	0.1	0.1	V
			6.0V	0	0.1	0.1	0.1	V
		V_{IN} = V_{IH} or V_{IL}						
		$\|I_{OUT}\| \le 4.0$ mA	4.5V	0.2	0.26	0.33	0.4	V
		$\|I_{OUT}\| \le 5.2$ mA	6.0V	0.2	0.26	0.33	0.4	V
I_{IN}	Maximum Input Current	V_{IN} = V_{CC} or GND	6.0V		±0.1	±1.0	±1.0	μA
I_{CC}	Maximum Quiescent Supply Current	V_{IN} = V_{CC} or GND	6.0V		2.0	20	40	μA
		I_{OUT} = 0 μA						

Note 4: For a power supply of 5V ±10% the worst case output voltages (V_{OH}, and V_{OL}) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC}=5.5V and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current (I_{IN}, I_{CC}, and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0V values should be used.

National Semiconductor

January 1988

MM54HC03/MM74HC03 Quad 2-Input Open Drain NAND Gate

General Description

These NAND gates utilize advanced silicon-gate CMOS technology to achieve operating speeds similar to LS-TTL gates with the low power consumption of standard CMOS integrated circuits. All gates have buffered outputs. All devices have high noise immunity and the ability to drive 10 LS-TTL loads. The 54HC/74HC logic family is functionally as well as pin-out compatible with the standard 54LS/74LS logic family. All inputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

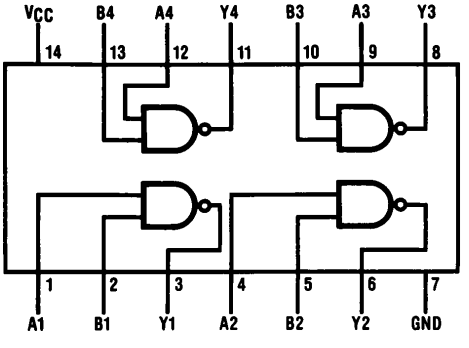
As with standard 54HC/74HC push-pull outputs there are diodes to both V_{CC} and ground. Therefore the output should not be pulled above V_{CC} as it would be clamped to one diode voltage above V_{CC}. This diode is added to enhance electrostatic protection.

Features

- Typical propagation delay: 12 ns
- Wide power supply range: 2–6V
- Low quiescent current: 20 μA maximum (74HC Series)
- Low input current: 1 μA maximum
- Fanout of 10 LS-TTL loads

Connection and Logic Diagrams

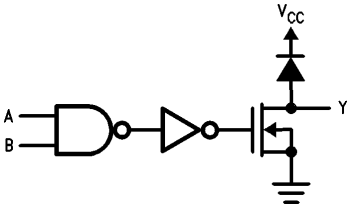
Dual-In-Line Package



TL/F/5295–1

Top View

Order Number MM54HC03 or MM74HC03



TL/F/5295–2

 TL/F/5295 RRD-B30M105/Printed in U. S. A.

Absolute Maximum Ratings (Notes 1 & 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage (V_{CC})	−0.5 to +7.0V
DC Input Voltage (V_{IN})	−1.5 to V_{CC} +1.5V
DC Output Voltage (V_{OUT})	−0.5 to V_{CC} +0.5V
Clamp Diode Current (I_{IK}, I_{OK})	±20 mA
DC Output Current, per pin (I_{OUT})	±25 mA
DC V_{CC} or GND Current, per pin (I_{CC})	±50 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C
Power Dissipation (P_D)	
(Note 3)	600 mW
S.O. Package only	500 mW
Lead Temp. (T_L) (Soldering 10 seconds)	260°C

Operating Conditions

	Min	Max	Units
Supply Voltage (V_{CC})	2	6	V
DC Input or Output Voltage (V_{IN}, V_{OUT})	0	V_{CC}	V
Operating Temp. Range (T_A)			
MM74HC	−40	+85	°C
MM54HC	−55	+125	°C
Input Rise or Fall Times (t_r, t_f) V_{CC} = 2.0V		1000	ns
V_{CC} = 4.5V		500	ns
V_{CC} = 6.0V		400	ns

DC Electrical Characteristics (Note 4)

Symbol	Parameter	Conditions	V_{CC}	T_A = 25°C	74HC T_A = −40 to 85°C	54HC T_A = −55 to 125°C	Units
				Typ	Guaranteed Limits		
V_{IH}	Minimum High Level Input Voltage		2.0V		1.5	1.5	1.5	V
			4.5V		3.15	3.15	3.15	V
			6.0V		4.2	4.2	4.2	V
V_{IL}	Maximum Low Level Input Voltage**		2.0V		0.5	0.5	0.5	V
			4.5V		1.35	1.35	1.35	V
			6.0V		1.8	1.8	1.8	V
V_{OL}	Minimum Low Level Output Voltage	V_{IN} = V_{IH} $\|I_{OUT}\| \le 20\ \mu A$ $R_L = \infty$	2.0V	0	0.1	0.1	0.1	V
			4.5V	0	0.1	0.1	0.1	V
			6.0V	0	0.1	0.1	0.1	V
		V_{IN} = V_{IH} $\|I_{OUT}\| \le 4.0$ mA	4.5V	0.2	0.26	0.33	0.4	V
		$\|I_{OUT}\| \le 5.2$ mA	6.0V	0.2	0.26	0.33	0.4	V
I_{LKG}	Maximum High Level Output Leakage Current	V_{IN} = V_{IH} or V_{IL} V_{OUT} = V_{CC}	6.0V		0.5	5	10	μA
I_{IN}	Maximum Input Current	V_{IN} = V_{CC} or GND	6.0V		±0.1	±1.0	±1.0	μA
I_{CC}	Maximum Quiescent Supply Current	V_{IN} = V_{CC} or GND I_{OUT} = 0 μA	6.0V		2.0	20	40	μA

Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: −12 mW/°C from 65°C to 85°C; ceramic "J" package: −12 mW/°C from 100°C to 125°C.

Note 4: For a power supply of 5V ±10% the worst case output voltages (V_{OH}, and V_{OL}) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC} = 5.5V and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current (I_{IN}, I_{CC}, and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0V values should be used.

**V_{IL} limits are currently tested at 20% of V_{CC}. The above V_{IL} specification (30% of V_{CC}) will be implemented no later than Q1, CY'89.

AC Electrical Characteristics $V_{CC}=5V$, $T_A=25°C$, $C_L=15$ pF, $t_r=t_f=6$ ns

Symbol	Parameter	Conditions	Typ	Guaranteed Limit	Units
t_{PZL}, t_{PLZ}	Maximum Propagation Delay	$R_L=1$ KΩ	10	20	ns

AC Electrical Characteristics

$V_{CC}=2.0V$ to 6.0V, $C_L=50$ pF, $t_r=t_f=6$ ns (unless otherwise specified)

Symbol	Parameter	Conditions	V_{CC}	$T_A=25°C$		74HC $T_A=-40$ to 85°C	54HC $T_A=-55$ to 125°C	Units
				Typ	Guaranteed Limits			
t_{PLZ}, t_{PZL}	Maximum Propagation Delay	$R_L=1$ KΩ	2.0V	63	125	158	186	ns
			4.5V	13	25	32	37	ns
			6.0V	11	21	27	32	ns
t_{THL}	Maximum Output Fall Time		2.0V	30	75	95	110	ns
			4.5V	8	15	19	22	ns
			6.0V	7	13	16	19	ns
C_{PD}	Power Dissipation Capacitance (Note 5)	(per gate)		20				pF
C_{IN}	Maximum Input Capacitance			5	10	10	10	pF

Note 5: C_{PD} determines the no load dynamic power consumption, $P_D=C_{PD}\,V_{CC}^2\,f+I_{CC}\,V_{CC}$, and the no load dynamic current consumption, $I_S=C_{PD}\,V_{CC}\,f+I_{CC}$. The power dissipated by R_L is not included.

FAIRCHILD SEMICONDUCTOR™

September 1983
Revised January 2005

MM74HC08
Quad 2-Input AND Gate

General Description

The MM74HC08 AND gates utilize advanced silicon-gate CMOS technology to achieve operating speeds similar to LS-TTL gates with the low power consumption of standard CMOS integrated circuits. The HC08 has buffered outputs, providing high noise immunity and the ability to drive 10 LS-TTL loads. The 74HC logic family is functionally as well as pin-out compatible with the standard 74LS logic family. All inputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

Features

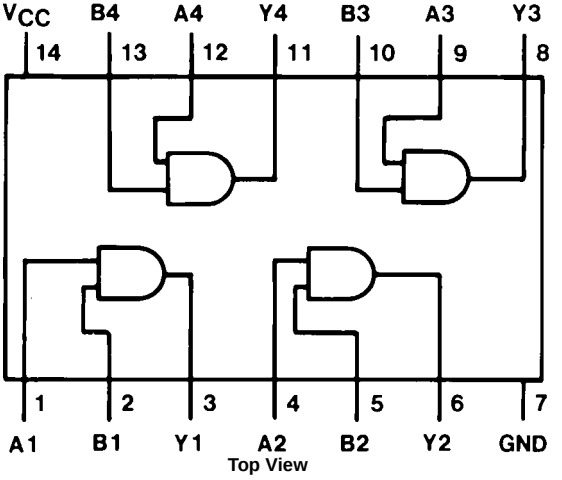
- Typical propagation delay: 7 ns (t_{PHL}), 12 ns (t_{PLH})
- Fanout of 10 LS-TTL loads
- Quiescent power consumption: 2 μA maximum at room temperature
- Low input current: 1 μA maximum

Ordering Code:

Order Number	Package Number	Package Description
MM74HC08M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC08MX_NL	M14A	Pb-Free 14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC08SJ	M14D	Pb-Free 14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC08MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC08MTCX-NL	MTC14	Pb-Free 14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC08N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code. (Tape and Reel not available in N14A)
Pb-Free package per JEDEC J-STD-020B.

Connection Diagram



Top View

Absolute Maximum Ratings(Note 1)

(Note 2)

Supply Voltage (V_{CC})	−0.5 to +7.0V
DC Input Voltage (V_{IN})	−1.5 to V_{CC} +1.5V
DC Output Voltage (V_{OUT})	−0.5 to V_{CC} +0.5V
Clamp Diode Current (I_{IK}, I_{OK})	±20 mA
DC Output Current, per pin (I_{OUT})	±25 mA
DC V_{CC} or GND Current, per pin (I_{CC})	±50 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C
Power Dissipation (P_D)	
(Note 3)	600 mW
S.O. Package only	500 mW
Lead Temperature (T_L)	
(Soldering 10 seconds)	260°C

Recommended Operating Conditions

		Min	Max	Units
Supply Voltage (V_{CC})		2	6	V
DC Input or Output Voltage (V_{IN}, V_{OUT})		0	V_{CC}	V
Operating Temperature Range (T_A)		−40	+85	°C
Input Rise or Fall Times				
(t_r, t_f)	V_{CC} = 2.0V		1000	ns
	V_{CC} = 4.5V		500	ns
	V_{CC} = 6.0V		400	ns

Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: −12 mW/°C from 65°C to 85°C.

DC Electrical Characteristics (Note 4)

Symbol	Parameter	Conditions	V_{CC}	T_A = 25°C	T_A = −40 to 85°C	T_A = −40 to 125°C	Units
				Typ	Guaranteed Limits		
V_{IH}	Minimum HIGH Level Input Voltage		2.0V		1.5	1.5	1.5	V
			4.5V		3.15	3.15	3.15	V
			6.0V		4.2	4.2	4.2	V
V_{IL}	Maximum LOW Level Input Voltage		2.0V		0.5	0.5	0.5	V
			4.5V		1.35	1.35	1.35	V
			6.0V		1.8	1.8	1.8	V
V_{OH}	Minimum HIGH Level Output Voltage	V_{IN} = V_{IH}						
		$\|I_{OUT}\| \le 20\ \mu A$	2.0V	2.0	1.9	1.9	1.9	V
			4.5V	4.5	4.4	4.4	4.4	V
			6.0V	6.0	5.9	5.9	5.9	V
		V_{IN} = V_{IH}						
		$\|I_{OUT}\| \le 4.0$ mA	4.5V	4.2	3.98	3.84	3.7	V
		$\|I_{OUT}\| \le 5.2$ mA	6.0V	5.7	5.48	5.34	5.2	V
V_{OL}	Maximum LOW Level Output Voltage	V_{IN} = V_{IH} or V_{IL}						
		$\|I_{OUT}\| \le 20\ \mu A$	2.0V	0	0.1	0.1	0.1	V
			4.5V	0	0.1	0.1	0.1	V
			6.0V	0	0.1	0.1	0.1	V
		V_{IN} = V_{IH} or V_{IL}						
		$\|I_{OUT}\| \le 4.0$ mA	4.5V	0.2	0.26	0.33	0.4	V
		$\|I_{OUT}\| \le 5.2$ mA	6.0V	0.2	0.26	0.33	0.4	V
I_{IN}	Maximum Input Current	V_{IN} = V_{CC} or GND	6.0V		±0.1	±1.0	±1.0	μA
I_{CC}	Maximum Quiescent Supply Current	V_{IN} = V_{CC} or GND	6.0V		2.0	20	40	μA
		I_{OUT} = 0 μA						

Note 4: For a power supply of 5V ±10% the worst case output voltages (V_{OH}, and V_{OL}) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC} = 5.5V and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current (I_{IN}, I_{CC}, and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0V values should be used.

FAIRCHILD SEMICONDUCTOR®

September 1983
Revised May 2005

MM74HC14
Hex Inverting Schmitt Trigger

General Description

The MM74HC14 utilizes advanced silicon-gate CMOS technology to achieve the low power dissipation and high noise immunity of standard CMOS, as well as the capability to drive 10 LS-TTL loads.

The 74HC logic family is functionally and pinout compatible with the standard 74LS logic family. All inputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

Features

- Typical propagation delay: 13 ns
- Wide power supply range: 2–6V
- Low quiescent current: 20 μA maximum (74HC Series)
- Low input current: 1 μA maximum
- Fanout of 10 LS-TTL loads
- Typical hysteresis voltage: 0.9V at V_{CC} = 4.5V

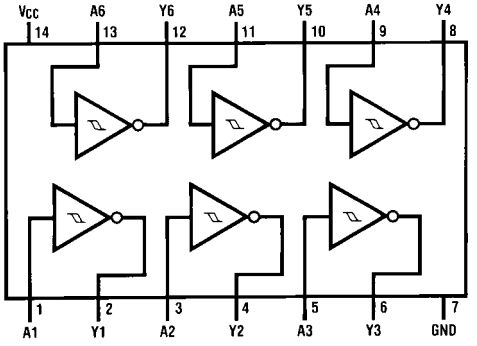
Ordering Code:

Order Number	Package Number	Package Description
MM74HC14M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC14MX_NL	M14A	Pb-Free 14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC14SJ	M14D	Pb-Free 14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC14MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC14MTCX_NL	MTC14	Pb-Free 14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC14N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
MM74HC14N_NL	N14A	Pb-Free 14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.
Pb-Free package per JEDEC J-STD-020B.

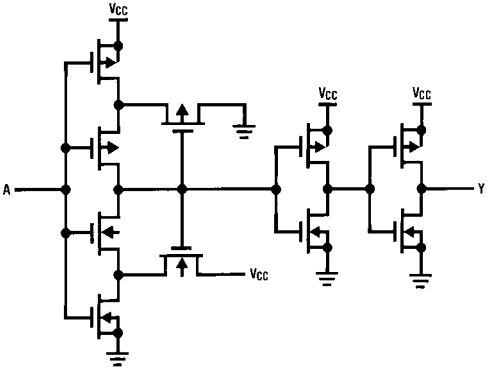
Connection Diagram

Pin Assignments for DIP, SOIC, SOP and TSSOP



Top View

Logic Diagram



Absolute Maximum Ratings (Note 1)

(Note 2)

Supply Voltage (V_{CC})	−0.5 to +7.0V
DC Input Voltage (V_{IN})	−1.5 to V_{CC} +1.5V
DC Output Voltage (V_{OUT})	−0.5 to V_{CC} +0.5V
Clamp Diode Current (I_{IK}, I_{OK})	±20 mA
DC Output Current, per pin (I_{OUT})	±25 mA
DC V_{CC} or GND Current, per pin (I_{CC})	±50 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C
Power Dissipation (P_D)	
(Note 3)	600 mW
S.O. Package only	500 mW
Lead Temperature (T_L)	
(Soldering 10 seconds)	260°C

Recommended Operating Conditions

	Min	Max	Units
Supply Voltage (V_{CC})	2	6	V
DC Input or Output Voltage (V_{IN}, V_{OUT})	0	V_{CC}	V
Operating Temperature Range (T_A)	−55	+125	°C

Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: −12 mW/°C from 65°C to 85°C.

DC Electrical Characteristics (Note 4)

Symbol	Parameter	Conditions	V_{CC}	T_A = 25°C	T_A = −40 to 85°C	T_A = −55 to 125°C	Units
				Typ	Guaranteed Limits		
V_{T+}	Positive Going Threshold Voltage	Minimum	2.0V	1.2	1.0	1.0	1.0	V
			4.5V	2.7	2.0	2.0	2.0	V
			6.0V	3.2	3.0	3.0	3.0	V
		Maximum	2.0V	1.2	1.5	1.5	1.5	V
			4.5V	2.7	3.15	3.15	3.15	V
			6.0V	3.2	4.2	4.2	4.2	V
V_{T-}	Negative Going Threshold Voltage	Minimum	2.0V	0.7	0.3	0.3	0.3	V
			4.5V	1.8	0.9	0.9	0.9	V
			6.0V	2.2	1.2	1.2	1.2	V
		Maximum	2.0V	0.7	1.0	1.0	1.0	V
			4.5V	1.8	2.2	2.2	2.2	V
			6.0V	2.2	3.0	3.0	3.0	V
V_H	Hysteresis Voltage	Minimum	2.0V	0.5	0.2	0.2	0.2	V
			4.5V	0.9	0.4	0.4	0.4	V
			6.0V	1.0	0.5	0.5	0.5	V
		Maximum	2.0V	0.5	1.0	1.0	1.0	V
			4.5V	0.9	1.4	1.4	1.4	V
			6.0V	1.0	1.5	1.5	1.5	V
V_{OH}	Minimum HIGH Level Output Voltage	V_{IN} = V_{IL} $\lvert I_{OUT}\rvert$ = 20 μA	2.0V	2.0	1.9	1.9	1.9	V
			4.5V	4.5	4.4	4.4	4.4	V
			6.0V	6.0	5.9	5.9	5.9	V
		V_{IN} = V_{IL}						
		$\lvert I_{OUT}\rvert$ = 4.0 mA	4.5V	4.2	3.98	3.84	3.7	V
		$\lvert I_{OUT}\rvert$ = 5.2 mA	6.0V	5.7	5.48	5.34	5.2	V
V_{OL}	Maximum LOW Level Output Voltage	V_{IN} = V_{IH} $\lvert I_{OUT}\rvert$ = 20 μA	2.0V	0	0.1	0.1	0.1	V
			4.5V	0	0.1	0.1	0.1	V
			6.0V	0	0.1	0.1	0.1	V
		V_{IN} = V_{IH}						
		$\lvert I_{OUT}\rvert$ = 4.0 mA	4.5V	0.2	0.26	0.33	0.4	V
		$\lvert I_{OUT}\rvert$ = 5.2 mA	6.0V	0.2	0.26	0.33	0.4	V
I_{IN}	Maximum Input Current	V_{IN} = V_{CC} or GND	6.0V		±0.1	±1.0	±1.0	μA
I_{CC}	Maximum Quiescent Supply Current	V_{IN} = V_{CC} or GND I_{OUT} = 0 μA	6.0V		2.0	20	40	μA

Note 4: For a power supply of 5V ±10% the worst case output voltages (V_{OH}, and V_{OL}) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC} = 5.5V and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current (I_{IN}, I_{CC}, and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0V values should be used.

AC Electrical Characteristics

V_{CC} = 5V, T_A = 25°C, C_L = 15 pF, $t_r = t_f$ = 6 ns

Symbol	Parameter	Conditions	Typ	Guaranteed Limit	Units
t_{PHL}, t_{PLH}	Maximum Propagation Delay		12	22	ns

AC Electrical Characteristics

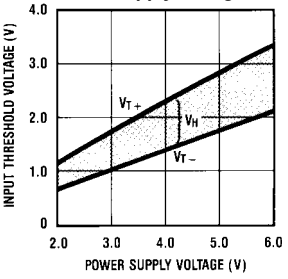
V_{CC} = 2.0V to 6.0V, C_L = 50 pF, $t_r = t_f$ = 6 ns (unless otherwise specified)

Symbol	Parameter	Conditions	V_{CC}	T_A = 25°C	T_A = −40 to 85°C	T_A = −55 to 125°C	Units
				Typ	Guaranteed Limits		
t_{PHL}, t_{PLH}	Maximum Propagation Delay		2.0V	60	125	156	188	ns
			4.5V	13	25	31	38	ns
			6.0V	11	21	26	32	ns
t_{TLH}, t_{THL}	Maximum Output Rise and Fall Time		2.0V	30	75	95	110	ns
			4.5V	8	15	19	22	ns
			6.0V	7	13	16	19	ns
C_{PD}	Power Dissipation Capacitance (Note 5)	(per gate)		27				pF
C_{IN}	Maximum Input Capacitance			5	10	10	10	pF

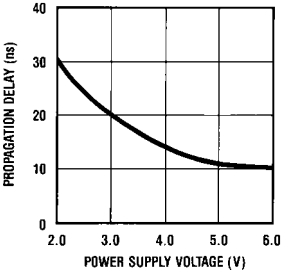
Note 5: C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} V_{CC} f + I_{CC}$.

Typical Performance Characteristics

Input Threshold, V_{T+}, V_{T-}, vs Power Supply Voltage

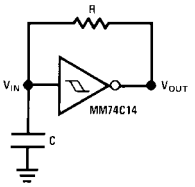


Propagation Delay vs Power Supply



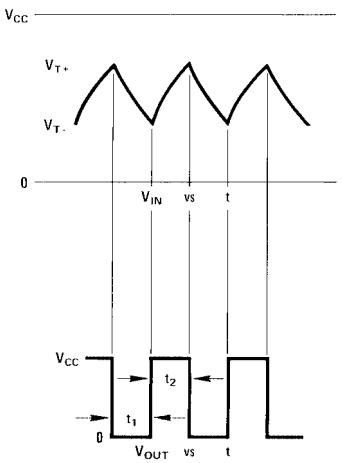
Typical Applications

Low Power Oscillator



$$t_1 \approx RC \ln \frac{V_{T+}}{V_{T-}}$$

$$t_2 \approx RC \ln \frac{V_{CC} - V_{T-}}{V_{CC} - V_{T+}}$$



$$f \approx \frac{1}{RC \ln \frac{V_{T+}(V_{CC} - V_{T-})}{V_{T-}(V_{CC} - V_{T+})}}$$

Note: The equations assume $t_1 + t_2 >> t_{pd0} + t_{pd1}$

FAIRCHILD SEMICONDUCTOR TM

August 1986
Revised March 2000

DM74LS14
Hex Inverter with Schmitt Trigger Inputs

General Description

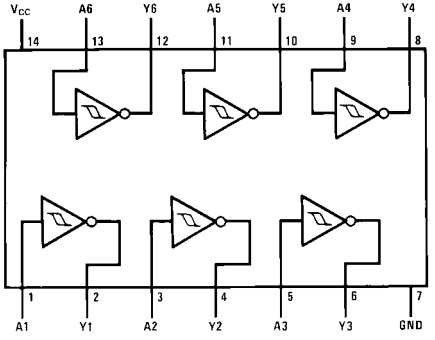
This device contains six independent gates each of which performs the logic INVERT function. Each input has hysteresis which increases the noise immunity and transforms a slowly changing input signal to a fast changing, jitter free output.

Ordering Code:

Order Number	Package Number	Package Description
DM74LS14M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
DM74LS14SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
DM74LS14N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Function Table

$$Y = \overline{A}$$

Input	Output
A	Y
L	H
H	L

H = HIGH Logic Level
L = LOW Logic Level

Absolute Maximum Ratings(Note 1)

Supply Voltage	7V
Input Voltage	7V
Operating Free Air Temperature Range	0°C to +70°C
Storage Temperature Range	−65°C to +150°C

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Recommended Operating Conditions

Symbol	Parameter	Min	Nom	Max	Units
V_{CC}	Supply Voltage	4.75	5	5.25	V
V_{T+}	Positive-Going Input Threshold Voltage (Note 2)	1.4	1.6	1.9	V
V_{T-}	Negative-Going Input Threshold Voltage (Note 2)	0.5	0.8	1	V
HYS	Input Hysteresis (Note 2)	0.4	0.8		V
I_{OH}	HIGH Level Output Current			−0.4	mA
I_{OL}	LOW Level Output Current			8	mA
T_A	Free Air Operating Temperature	0		70	°C

Note 2: V_{CC} = 5V.

Electrical Characteristics

over recommended operating free air temperature range (unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ (Note 3)	Max	Units
V_I	Input Clamp Voltage	V_{CC} = Min, I_I = −18 mA			−1.5	V
V_{OH}	HIGH Level Output Voltage	V_{CC} = Min, I_{OH} = Max, V_{IL} = Max	2.7	3.4		V
V_{OL}	LOW Level Output Voltage	V_{CC} = Min, I_{OL} = Max, V_{IH} = Min		0.35	0.5	V
		V_{CC} = Min, I_{OL} = 4 mA		0.25	0.4	
I_{T+}	Input Current at Positive-Going Threshold	V_{CC} = 5V, V_I = V_{T+}		−0.14		mA
I_{T-}	Input Current at Negative-Going Threshold	V_{CC} = 5V, V_I = V_{T-}		−0.18		mA
I_I	Input Current @ Max Input Voltage	V_{CC} = Max, V_I = 7V			0.1	mA
I_{IH}	HIGH Level Input Current	V_{CC} = Max, V_I = 2.7V			20	µA
I_{IL}	LOW Level Input Current	V_{CC} = Max, V_I = 0.4V			−0.4	mA
I_{OS}	Short Circuit Output Current	V_{CC} = Max (Note 4)	−20		−100	mA
I_{CCH}	Supply Current with Outputs HIGH	V_{CC} = Max		8.6	16	mA
I_{CCL}	Supply Current with Outputs LOW	V_{CC} = Max		12	21	mA

Note 3: All typicals are at V_{CC} = 5V, T_A = 25°C.

Note 4: Not more than one output should be shorted at a time, and the duration should not exceed one second.

Switching Characteristics

at V_{CC} = 5V and T_A = 25°C

Symbol	Parameter	R_L = 2 kΩ				Units
		C_L = 15 pF		C_L = 50 pF		
		Min	Max	Min	Max	
t_{PLH}	Propagation Delay Time LOW-to-HIGH Level Output	5	22	8	25	ns
t_{PHL}	Propagation Delay Time HIGH-to-LOW Level Output	5	22	10	33	ns

FAIRCHILD SEMICONDUCTOR™

September 1983
Revised January 2005

MM74HC32
Quad 2-Input OR Gate

General Description

The MM74HC32 OR gates utilize advanced silicon-gate CMOS technology to achieve operating speeds similar to LS-TTL gates with the low power consumption of standard CMOS integrated circuits. All gates have buffered outputs providing high noise immunity and the ability to drive 10 LS-TTL loads. The 74HC logic family is functionally as well as pin-out compatible with the standard 74LS logic family. All inputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

Features

- Typical propagation delay: 10 ns
- Wide power supply range: 2–6V
- Low quiescent current: 20 μA maximum (74HC Series)
- Low input current: 1 μA maximum
- Fanout of 10 LS-TTL loads

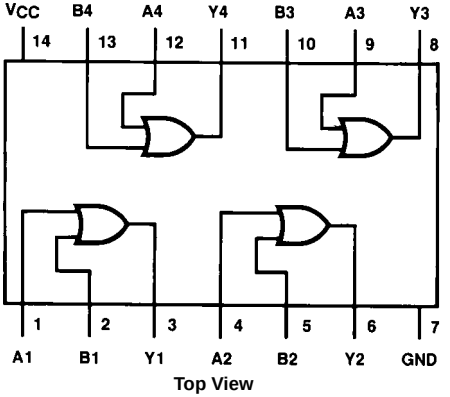
Ordering Code:

Order Number	Package Number	Package Description
MM74HC32M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC32MX_NL	M14A	Pb-Free 14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC32SJ	M14D	Pb-Free 14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC32MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC32MTCX_NL	MTC14	Pb-Free 14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC32N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
MM74HC32N_NL	N14A	Pb-Free 14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.
Pb-Free package per JEDEC J-STD-020B.

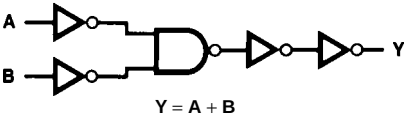
Connection Diagram

Pin Assignments for DIP, SOIC, SOP and TSSOP



Top View

Logic Diagram



$Y = A + B$
(1 of 4)

Absolute Maximum Ratings (Note 1)

(Note 2)

Supply Voltage (V_{CC})	−0.5 to + 7.0V
DC Input Voltage (V_{IN})	−1.5 to V_{CC} + 1.5V
DC Output Voltage (V_{OUT})	−0.5 to V_{CC} + 0.5V
Clamp Diode Current (I_{IK}, I_{OK})	±20 mA
DC Output Current, per pin (I_{OUT})	±25 mA
DC V_{CC} or GND Current, per pin (I_{CC})	±50 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C
Power Dissipation (P_D)	
(Note 3)	600 mW
S.O. Package only	500 mW
Lead Temperature (T_L)	
(Soldering 10 seconds)	260°C

Recommended Operating Conditions

	Min	Max	Units
Supply Voltage (V_{CC})	2	6	V
DC Input or Output Voltage (V_{IN}, V_{OUT})	0	V_{CC}	V
Operating Temperature Range (T_A)	−40	+85	°C
Input Rise or Fall Times			
(t_r, t_f) V_{CC} = 2.0V		1000	ns
V_{CC} = 4.5V		500	ns
V_{CC} = 6.0V		400	ns

Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: −12 mW/°C from 65°C to 85°C.

DC Electrical Characteristics (Note 4)

Symbol	Parameter	Conditions	V_{CC}	T_A = 25°C	T_A = −40 to 85°C		Units
				Typ	Guaranteed Limits		
V_{IH}	Minimum HIGH Level Input Voltage		2.0V		1.5	1.5	V
			4.5V		3.15	3.15	V
			6.0V		4.2	4.2	V
V_{IL}	Maximum LOW Level Input Voltage		2.0V		0.5	0.5	V
			4.5V		1.35	1.35	V
			6.0V		1.8	1.8	V
V_{OH}	Minimum HIGH Level Output Voltage	V_{IN} = V_{IH} or V_{IL} $\lvert I_{OUT} \rvert \leq$ 20 μA	2.0V	2.0	1.9	1.9	V
			4.5V	4.5	4.4	4.4	V
			6.0V	6.0	5.9	5.9	V
		V_{IN} = V_{IH} or V_{IL} $\lvert I_{OUT} \rvert \leq$ 4.0 mA	4.5V	4.7	3.98	3.84	V
		$\lvert I_{OUT} \rvert \leq$ 5.2 mA	6.0V	5.2	5.48	5.34	V
V_{OL}	Maximum LOW Level Output Voltage	V_{IN} = V_{IL} $\lvert I_{OUT} \rvert \leq$ 20 μA	2.0V	0	0.1	0.1	V
			4.5V	0	0.1	0.1	V
			6.0V	0	0.1	0.1	V
		V_{IN} = V_{IL} $\lvert I_{OUT} \rvert \leq$ 4.0 mA	4.5V	0.2	0.26	0.33	V
		$\lvert I_{OUT} \rvert \leq$ 5.2 mA	6.0V	0.2	0.26	0.33	V
I_{IN}	Maximum Input Current	V_{IN} = V_{CC} or GND	6.0V		±0.1	±1.0	μA
I_{CC}	Maximum Quiescent Supply Current	V_{IN} = V_{CC} or GND I_{OUT} = 0 μA	6.0V		2.0	20	μA

Note 4: For a power supply of 5V ±10% the worst case output voltages (V_{OH}, and V_{OL}) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC} = 5.5V and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current (I_{IN}, I_{CC}, and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0V values should be used.

AC Electrical Characteristics

V_{CC} = 5V, T_A = 25°C, C_L = 15 pF, t_r = t_f = 6 ns

Symbol	Parameter	Conditions	Typ	Guaranteed Limit	Units
t_{PHL}, t_{PLH}	Maximum Propagation Delay		10	18	ns

AC Electrical Characteristics

V_{CC} = 2.0V to 6.0V, C_L = 50 pF, t_r = t_f = 6 ns (unless otherwise specified)

Symbol	Parameter	Conditions	V_{CC}	T_A = 25°C		T_A = −40 to 85°C	Units
				Typ	Guaranteed Limits		
t_{PHL}, t_{PLH}	Maximum Propagation Delay		2.0V	30	100	125	ns
			4.5V	12	20	25	ns
			6.0V	9	17	21	ns
t_{TLH}, t_{THL}	Maximum Output Rise and Fall Time		2.0V	30	75	95	ns
			4.5V	8	15	19	ns
			6.0V	7	13	16	ns
C_{PD}	Power Dissipation Capacitance (Note 5)	(per gate)		50			pF
C_{IN}	Maximum Input Capacitance			5	10	10	pF

Note 5: C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} V_{CC} f + I_{CC}$.

October 1988
Revised March 2000

DM74LS47
BCD to 7-Segment Decoder/Driver with Open-Collector Outputs

General Description

The DM74LS47 accepts four lines of BCD (8421) input data, generates their complements internally and decodes the data with seven AND/OR gates having open-collector outputs to drive indicator segments directly. Each segment output is guaranteed to sink 24 mA in the ON (LOW) state and withstand 15V in the OFF (HIGH) state with a maximum leakage current of 250 μA. Auxiliary inputs provided blanking, lamp test and cascadable zero-suppression functions.

Features

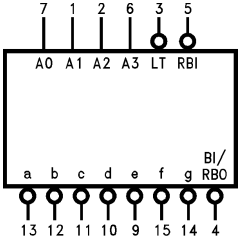
- Open-collector outputs
- Drive indicator segments directly
- Cascadable zero-suppression capability
- Lamp test input

Ordering Code:

Order Number	Package Number	Package Description
DM74LS47M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
DM74LS47N	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

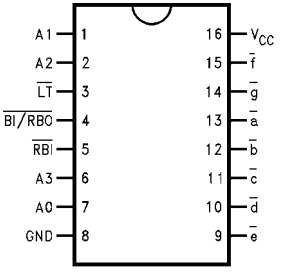
Logic Symbol



V_{CC} = Pin 16

GND = Pin 8

Connection Diagram



Pin Descriptions

Pin Names	Description
A0–A3	BCD Inputs
$\overline{RBI}$	Ripple Blanking Input (Active LOW)
$\overline{LT}$	Lamp Test Input (Active LOW)
$\overline{BI}/\overline{RBO}$	Blanking Input (Active LOW) or Ripple Blanking Output (Active LOW)
$\overline{a}$ –$\overline{g}$	Segment Outputs (Active LOW) (Note 1)

Note 1: OC—Open Collector

Truth Table

Decimal or Function	Inputs							Outputs							Note
	$\overline{LT}$	$\overline{RBI}$	A3	A2	A1	A0	$\overline{BI/RBO}$	a	b	c	d	e	f	g	
0	H	H	L	L	L	L	H	L	L	L	L	L	L	H	(Note 2)
1	H	X	L	L	L	H	H	H	L	L	H	H	H	H	(Note 2)
2	H	X	L	L	H	L	H	L	L	H	L	L	H	L	
3	H	X	L	L	H	H	H	L	L	L	L	H	H	L	
4	H	X	L	H	L	L	H	H	L	L	H	H	L	L	
5	H	X	L	H	L	H	H	L	H	L	L	H	L	L	
6	H	X	L	H	H	L	H	H	H	L	L	L	L	L	
7	H	X	L	H	H	H	H	L	L	L	H	H	H	H	
8	H	X	H	L	L	L	H	L	L	L	L	L	L	L	
9	H	X	H	L	L	H	H	L	L	L	H	H	L	L	
10	H	X	H	L	H	L	H	H	H	H	L	L	H	L	
11	H	X	H	L	H	H	H	H	H	L	L	H	H	L	
12	H	X	H	H	L	L	H	H	L	H	H	H	L	L	
13	H	X	H	H	L	H	H	L	H	H	L	H	L	L	
14	H	X	H	H	H	L	H	H	H	H	L	L	L	L	
15	H	X	H	H	H	H	H	H	H	H	H	H	H	H	
$\overline{BI}$	X	X	X	X	X	X	L	H	H	H	H	H	H	H	(Note 3)
$\overline{RBI}$	H	L	L	L	L	L	L	H	H	H	H	H	H	H	(Note 4)
$\overline{LT}$	L	X	X	X	X	X	H	L	L	L	L	L	L	L	(Note 5)

Note 2: $\overline{BI/RBO}$ is wire-AND logic serving as blanking input ($\overline{BI}$) and/or ripple-blanking output ($\overline{RBO}$). The blanking out ($\overline{BI}$) must be open or held at a HIGH level when output functions 0 through 15 are desired, and ripple-blanking input ($\overline{RBI}$) must be open or at a HIGH level if blanking or a decimal 0 is not desired. X = input may be HIGH or LOW.

Note 3: When a LOW level is applied to the blanking input (forced condition) all segment outputs go to a HIGH level regardless of the state of any other input condition.

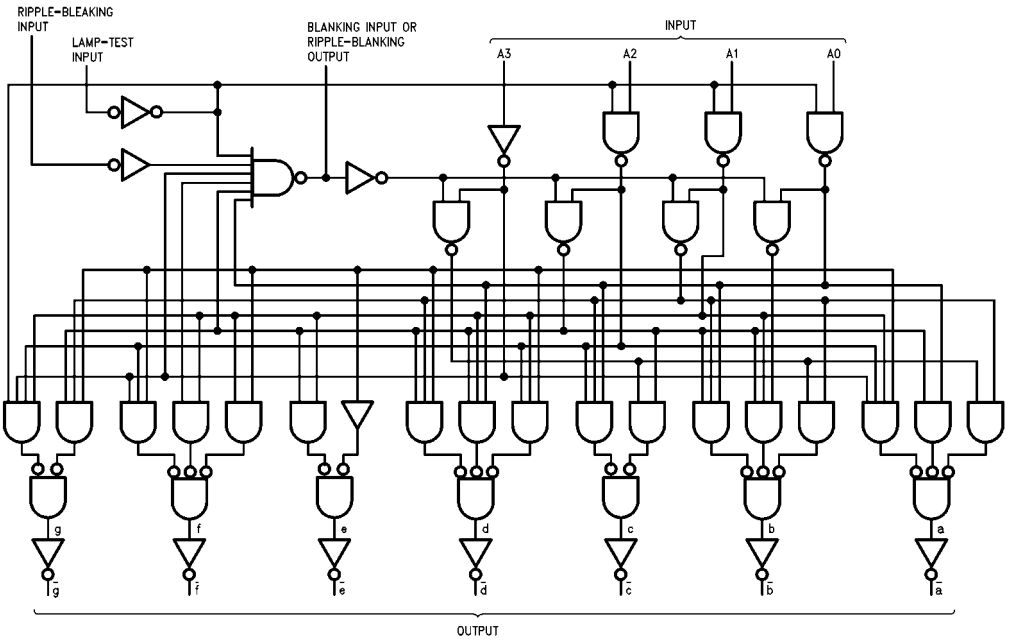
Note 4: When ripple-blanking input ($\overline{RBI}$) and inputs A0, A1, A2 and A3 are LOW level, with the lamp test input at HIGH level, all segment outputs go to a HIGH level and the ripple-blanking output ($\overline{RBO}$) goes to a LOW level (response condition).

Note 5: When the blanking input/ripple-blanking output ($\overline{BI/RBO}$) is OPEN or held at a HIGH level, and a LOW level is applied to lamp test input, all segment outputs go to a LOW level.

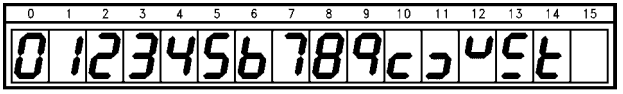
Functional Description

The DM74LS47 decodes the input data in the pattern indicated in the Truth Table and the segment identification illustration. If the input data is decimal zero, a LOW signal applied to the $\overline{RBI}$ blanks the display and causes a multi-digit display. For example, by grounding the $\overline{RBI}$ of the highest order decoder and connecting its $\overline{BI/RBO}$ to $\overline{RBI}$ of the next lowest order decoder, etc., leading zeros will be suppressed. Similarly, by grounding $\overline{RBI}$ of the lowest order decoder and connecting its $\overline{BI/RBO}$ to $\overline{RBI}$ of the next highest order decoder, etc., trailing zeros will be suppressed. Leading and trailing zeros can be suppressed simultaneously by using external gates, i.e.: by driving $\overline{RBI}$ of a intermediate decoder from an OR gate whose inputs are $\overline{BI/RBO}$ of the next highest and lowest order decoders. $\overline{BI/RBO}$ also serves as an unconditional blanking input. The internal NAND gate that generates the $\overline{RBO}$ signal has a resistive pull-up, as opposed to a totem pole, and thus $\overline{BI/RBO}$ can be forced LOW by external means, using wired-collector logic. A LOW signal thus applied to $\overline{BI/RBO}$ turns off all segment outputs. This blanking feature can be used to control display intensity by varying the duty cycle of the blanking signal. A LOW signal applied to $\overline{LT}$ turns on all segment outputs, provided that $\overline{BI/RBO}$ is not forced LOW.

Logic Diagram



Numerical Designations—Resultant Displays



Absolute Maximum Ratings(Note 6)

Supply Voltage	7V
Input Voltage	7V
Operating Free Air Temperature Range	0°C to +70°C
Storage Temperature Range	−65°C to +150°C

Note 6: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Recommended Operating Conditions

Symbol	Parameter	Min	Nom	Max	Units
V_{CC}	Supply Voltage	4.75	5	5.25	V
V_{IH}	HIGH Level Input Voltage	2			V
V_{IL}	LOW Level Input Voltage			0.8	V
I_{OH}	HIGH Level Output Current $\overline{a} - \overline{g}$ @ 15V = V_{OH} (Note 7)			−250	µA
I_{OH}	HIGH Level Output Current $\overline{BI}$ /$\overline{RBO}$			−50	µA
I_{OL}	LOW Level Output Current			24	mA
T_A	Free Air Operating Temperature	0		70	°C

Note 7: OFF-State at $\overline{a}$–$\overline{g}$.

Electrical Characteristics

Over recommended operating free air temperature range (unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ (Note 8)	Max	Units
V_I	Input Clamp Voltage	V_{CC} = Min, I_I = −18 mA			−1.5	V
V_{OH}	HIGH Level Output Voltage	V_{CC} = Min, I_{OH} = Max, V_{IL} = Max, $\overline{BI}$ /$\overline{RBO}$	2.7	3.4		V
I_{OFF}	Output HIGH Current Segment Outputs	V_{CC} = 5.5V, V_O = 15V $\overline{a} - \overline{g}$			250	µA
V_{OL}	LOW Level Output Voltage	V_{CC} = Min, I_{OL} = Max, V_{IH} = Min, $\overline{a} - \overline{g}$		0.35	0.5	V
		I_{OL} = 3.2 mA, $\overline{BI}$ /$\overline{RBO}$			0.5	
		I_{OL} = 12 mA, $\overline{a} - \overline{g}$		0.25	0.4	
		I_{OL} = 1.6 mA, $\overline{BI}$ /$\overline{RBO}$			0.4	
I_I	Input Current @ Max Input Voltage	V_{CC} = Max, V_I = 7V			100	µA
		V_{CC} = Max, V_I = 10V				
I_{IH}	HIGH Level Input Current	V_{CC} = Max, V_I = 2.7V			20	µA
I_{IL}	LOW Level Input Current	V_{CC} = Max, V_I = 0.4V			−0.4	mA
I_{OS}	Short Circuit Output Current	V_{CC} = Max (Note 9), I_{OS} at $\overline{BI}$/$\overline{RBO}$	−0.3		−2.0	mA
I_{CC}	Supply Current	V_{CC} = Max			13	mA

Note 8: All typicals are at V_{CC} = 5V, T_A = 25°C.

Note 9: Not more than one output should be shorted at a time, and the duration should not exceed one second.

Switching Characteristics

at V_{CC} = +5.0V, T_A = +25°C

Symbol	Parameter	Conditions	R_L = 665Ω, C_L = 15 pF		Units
			Min	Max	
t_{PLH} t_{PHL}	Propagation Delay An to $\overline{a}$ –$\overline{g}$			100 100	ns
t_{PLH} t_{PHL}	Propagation Delay $\overline{RBI}$ to $\overline{a}$ –$\overline{g}$ (Note 10)			100 100	ns

Note 10: $\overline{LT}$ = HIGH, A0–A3 = LOW

FAIRCHILD SEMICONDUCTOR™

September 1983
Revised January 2005

MM74HC74A
Dual D-Type Flip-Flop with Preset and Clear

General Description

The MM74HC74A utilizes advanced silicon-gate CMOS technology to achieve operating speeds similar to the equivalent LS-TTL part. It possesses the high noise immunity and low power consumption of standard CMOS integrated circuits, along with the ability to drive 10 LS-TTL loads.

This flip-flop has independent data, preset, clear, and clock inputs and Q and $\overline{Q}$ outputs. The logic level present at the data input is transferred to the output during the positive-going transition of the clock pulse. Preset and clear are independent of the clock and accomplished by a low level at the appropriate input.

The 74HC logic family is functionally and pinout compatible with the standard 74LS logic family. All inputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

Features

- Typical propagation delay: 20 ns
- Wide power supply range: 2–6V
- Low quiescent current: 40 μA maximum (74HC Series)
- Low input current: 1 μA maximum
- Fanout of 10 LS-TTL loads

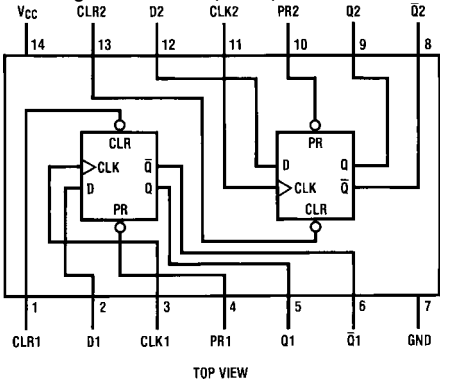
Ordering Code:

Order Number	Package Number	Package Description
MM74HC74AM	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC74AMX_NL	M14A	Pb-Free 14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC74ASJ	M14D	Pb-Free 14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC74AMTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC74AMTCX_NL	MTC14	Pb-Free 14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC74AN	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.
Pb-Free package per JEDEC J-STD-020B.

Connection Diagram

Pin Assignments for DIP, SOIC, SOP and TSSOP



TOP VIEW

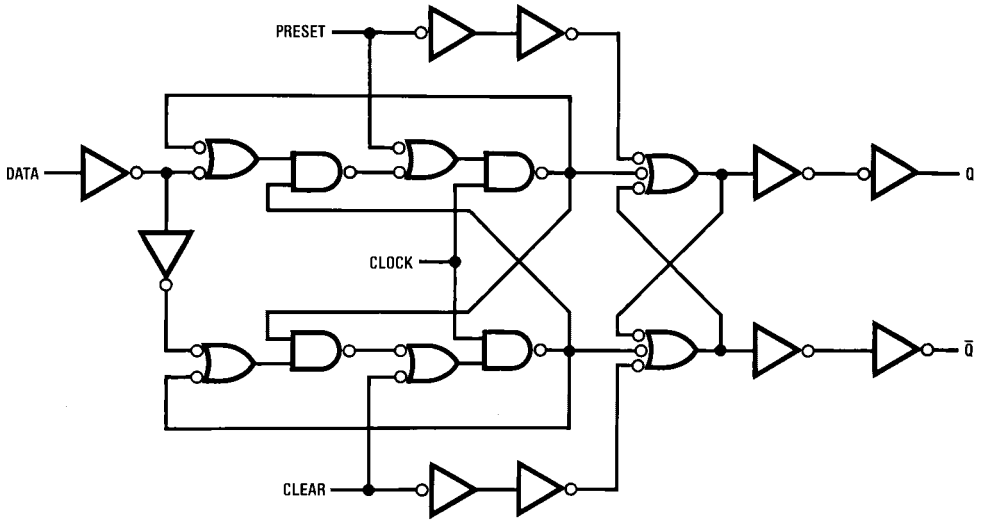
Truth Table

Inputs				Outputs	
PR	CLR	CLK	D	Q	$\overline{Q}$
L	H	X	X	H	L
H	L	X	X	L	H
L	L	X	X	H (Note 1)	H (Note 1)
H	H	↑	H	H	L
H	H	↑	L	L	H
H	H	L	X	Q0	$\overline{Q}$ 0

Note: Q0 = the level of Q before the indicated input conditions were established.

Note 1: This configuration is nonstable; that is, it will not persist when preset and clear inputs return to their inactive (HIGH) level.

Logic Diagram



Absolute Maximum Ratings (Note 2)

(Note 3)

Supply Voltage (V_{CC})	−0.5 to +7.0V
DC Input Voltage (V_{IN})	−1.5 to V_{CC} +1.5V
DC Output Voltage (V_{OUT})	−0.5 to V_{CC} +0.5V
Clamp Diode Current (I_{IK}, I_{OK})	±20 mA
DC Output Current, per pin (I_{OUT})	±25 mA
DC V_{CC} or GND Current, per pin (I_{CC})	±50 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C
Power Dissipation (P_D)	
(Note 4)	600 mW
S.O. Package only	500 mW
Lead Temperature (T_L)	
(Soldering 10 seconds)	260°C

Recommended Operating Conditions

	Min	Max	Units
Supply Voltage (V_{CC})	2	6	V
DC Input or Output Voltage (V_{IN}, $_{OUT}$)	0	V_{CC}	V
Operating Temperature Range (T_A)	−40	+85	°C
Input Rise or Fall Times			
(t_r, t_f) V_{CC} = 2.0V		1000	ns
V_{CC} = 4.5V		500	ns
V_{CC} = 6.0V		400	ns

Note 2: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Note 3: Unless otherwise specified all voltages are referenced to ground.

Note 4: Power Dissipation temperature derating — plastic "N" package: −12 mW/°C from 65°C to 85°C.

DC Electrical Characteristics (Note 5)

Symbol	Parameter	Conditions	V_{CC}	T_A = 25°C	T_A = −40 to 85°C	T_A = −55 to 125°C	Units
				Typ	Guaranteed Limits		
V_{IH}	Minimum HIGH Level Input Voltage		2.0V		1.5	1.5	1.5	V
			4.5V		3.15	3.15	3.15	V
			6.0V		4.2	4.2	4.2	V
V_{IL}	Maximum LOW Level Input Voltage		2.0V		0.5	0.5	0.5	V
			4.5V		1.35	1.35	1.35	V
			6.0V		1.8	1.8	1.8	V
V_{OH}	Minimum HIGH Level Output Voltage	V_{IN} = V_{IH} or V_{IL}						
		$\|I_{OUT}\| \le 20$ µA	2.0V	2.0	1.9	1.9	1.9	V
			4.5V	4.5	4.4	4.4	4.4	V
			6.0V	6.0	5.9	5.9	5.9	V
		V_{IN} = V_{IH} or V_{IL}						
		$\|I_{OUT}\| \le 4.0$ mA	4.5V	4.3	3.98	3.84	3.7	V
		$\|I_{OUT}\| \le 5.2$ mA	6.0V	5.2	5.48	5.34	5.2	V
V_{OL}	Maximum LOW Level Output Voltage	V_{IN} = V_{IH} or V_{IL}						
		$\|I_{OUT}\| \le 20$ µA	2.0V	0	0.1	0.1	0.1	V
			4.5V	0	0.1	0.1	0.1	V
			6.0V	0	0.1	0.1	0.1	V
		V_{IN} = V_{IH} or V_{IL}						
		$\|I_{OUT}\| \le 4.0$ mA	4.5V	0.2	0.26	0.33	0.4	V
		$\|I_{OUT}\| \le 5.2$ mA	6.0V	0.2	0.26	0.33	0.4	V
I_{IN}	Maximum Input Current	V_{IN} = V_{CC} or GND	6.0V		±0.1	±1.0	±1.0	µA
I_{CC}	Maximum Quiescent Supply Current	$V_{I N}$ =V_{CC} or GND	6.0V		4.0	40	80	µA
		I_{OUT} = 0 µA						

Note 5: For a power supply of 5V ±10% the worst case output voltages (V_{OH}, and V_{OL}) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC} = 5.5V and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current (I_{IN}, I_{CC}, and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0V values should be used.

AC Electrical Characteristics

V_{CC} = 5V, T_A = 25°C, C_L = 15 pF, $t_r = t_f$ = 6 ns

Symbol	Parameter	Conditions	Typ	Guaranteed Limit	Units
f_{MAX}	Maximum Operating Frequency		72	30	MHz
t_{PHL}, t_{PLH}	Maximum Propagation Delay Clock to Q or $\overline{Q}$		10	30	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay Preset or Clear to Q or $\overline{Q}$		17	40	ns
t_{REM}	Minimum Removal Time, Preset or Clear to Clock		6	5	ns
t_S	Minimum Setup Time Data to Clock		10	20	ns
t_H	Minimum Hold Time Clock to Data		0	0	ns
t_W	Minimum Pulse Width Clock, Preset or Clear		8	16	ns

AC Electrical Characteristics

C_L = 50 pF, $t_r = t_f$ = 6 ns (unless otherwise specified)

Symbol	Parameter	Conditions	V_{CC}	T_A = 25°C	T_A = −40 to 85°C	T_A = −55 to 125°C	Units
				Typ	Guaranteed Limits		
f_{MAX}	Maximum Operating Frequency		2.0V	22	6	5	4	MHz
			4.5V	72	30	24	20	MHz
			6.0V	94	35	28	24	MHz
t_{PHL}, t_{PLH}	Maximum Propagation Delay Clock to Q or $\overline{Q}$		2.0V	34	110	140	165	ns
			4.5V	12	22	28	33	ns
			6.0V	10	19	24	28	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay Preset or Clear To Q or $\overline{Q}$		2.0V	66	150	190	225	ns
			4.5V	20	30	38	45	ns
			6.0V	16	26	33	38	ns
t_{REM}	Minimum Removal Time Preset or Clear To Clock		2.0V	20	50	65	75	ns
			4.5V	6	10	13	15	ns
			6.0V	5	9	11	13	ns
t_S	Minimum Setup Time Data to Clock		2.0V	35	80	100	120	ns
			4.5V	10	16	20	24	ns
			6.0V	8	14	17	20	ns
t_H	Minimum Hold Time Clock to Data		2.0V		0	0	0	ns
			4.5V		0	0	0	ns
			6.0V		0	0	0	ns
t_W	Minimum, Pulse Width Clock, Preset or Clear		2.0V	30	80	101	119	ns
			4.5V	9	16	20	24	ns
			6.0V	8	14	17	20	ns
t_{TLH}, t_{THL}	Maximum Output Rise and Fall Time		2.0V	25	75	95	110	ns
			4.5V	7	15	19	22	ns
			6.0V	6	13	16	19	ns
t_r, t_f	Maximum Input Rise and Fall Time		2.0V		1000	1000	1000	ns
			4.5V		500	500	500	ns
			6.0V		400	400	400	ns
C_{PD}	Power Dissipation Capacitance (Note 6)	(per flip-flop)		80				pF
C_{IN}	Maximum Input Capacitance			5	10	10	10	pF

Note 6: C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} V_{CC} f + I_{CC}$.

FAIRCHILD SEMICONDUCTOR™

September 1983
Revised January 2005

MM74HC86
Quad 2-Input Exclusive OR Gate

General Description

The MM74HC86 EXCLUSIVE OR gate utilizes advanced silicon-gate CMOS technology to achieve operating speeds similar to equivalent LS-TTL gates while maintaining the low power consumption and high noise immunity characteristic of standard CMOS integrated circuits. These gates are fully buffered and have a fanout of 10 LS-TTL loads. The 74HC logic family is functionally as well as pin out compatible with the standard 74LS logic family. All inputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

Features

- Typical propagation delay: 9 ns
- Wide operating voltage range: 2–6V
- Low input current: 1 μA maximum
- Low quiescent current: 20 μA maximum (74 Series)
- Output drive capability: 10 LS-TTL loads

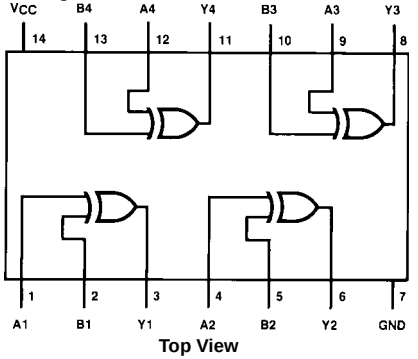
Ordering Code:

Order Number	Package Number	Package Description
MM74HC86M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC86MX_NL	M14A	Pb-Free 14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC86SJ	M14D	Pb-Free 14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC86MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC86N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
MM74HC86NX_NL	N14A	Pb-Free 14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.
Pb-Free package per JEDEC J-STD-020B.

Connection Diagram

Pin Assignments for DIP, SOIC, SOP and TSSOP



Top View

Truth Table

Inputs		Outputs
A	B	Y
L	L	L
L	H	H
H	L	H
H	H	L

$Y = A \oplus B = \overline{A}\,B + A\overline{B}$

Absolute Maximum Ratings(Note 1)

(Note 2)

Supply Voltage (V_{CC})	−0.5 to +7.0V
DC Input Voltage (V_{IN})	−1.5 to V_{CC} +1.5V
DC Output Voltage (V_{OUT})	−0.5 to V_{CC} +0.5V
Clamp Diode Current (I_{IK}, I_{OK})	±20 mA
DC Output Current, per pin (I_{OUT})	±25 mA
DC V_{CC} or GND Current, per pin (I_{CC})	±50 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C
Power Dissipation (P_D)	
(Note 3)	600 mW
S.O. Package only	500 mW
Lead Temperature (T_L)	
(Soldering 10 seconds)	260°C

Recommended Operating Conditions

	Min	Max	Units
Supply Voltage (V_{CC})	2	6	V
DC Input or Output Voltage (V_{IN}, V_{OUT})	0	V_{CC}	V
Operating Temperature Range (T_A)	−40	+85	°C
Input Rise or Fall Times			
(t_r, t_f) V_{CC} = 2.0V		1000	ns
V_{CC} = 4.5V		500	ns
V_{CC} = 6.0V		400	ns

Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: −12 mW/°C from 65°C to 85°C.

DC Electrical Characteristics (Note 4)

Symbol	Parameter	Conditions	V_{CC}	T_A = 25°C	T_A = −40 to 85°C	T_A = −55 to 125°C	Units
				Typ	Guaranteed Limits		
V_{IH}	Minimum HIGH Level Input Voltage		2.0V		1.5	1.5	1.5	V
			4.5V		3.15	3.15	3.15	V
			6.0V		4.2	4.2	4.2	V
V_{IL}	Maximum LOW Level Input Voltage		2.0V		0.5	0.5	0.5	V
			4.5V		1.35	1.35	1.35	V
			6.0V		1.8	1.8	1.8	V
V_{OH}	Minimum HIGH Level Output Voltage	V_{IN} = V_{IH} or V_{IL}						
		$\|I_{OUT}\| \leq$ 20 μA	2.0V	2.0	1.9	1.9	1.9	V
			4.5V	4.5	4.4	4.4	4.4	V
			6.0V	6.0	5.9	5.9	5.9	V
		V_{IN} = V_{IH} or V_{IL}						
		$\|I_{OUT}\| \leq$ 4.0 mA	4.5V	4.2	3.98	3.84	3.7	V
		$\|I_{OUT}\| \leq$ 5.2 mA	6.0V	5.7	5.48	5.34	5.2	V
V_{OL}	Maximum LOW Level Output Voltage	V_{IN} = V_{IH} or V_{IL}						
		$\|I_{OUT}\| \leq$ 20 μA	2.0V	0	0.1	0.1	0.1	V
			4.5V	0	0.1	0.1	0.1	V
			6.0V	0	0.1	0.1	0.1	V
		V_{IN} = V_{IH} or V_{IL}						
		$\|I_{OUT}\| \leq$ 4.0 mA	4.5V	0.2	0.26	0.33	0.4	V
		$\|I_{OUT}\| \leq$ 5.2 mA	6.0V	0.2	0.26	0.33	0.4	V
I_{IN}	Maximum Input Current	V_{IN} = V_{CC} or GND	6.0V		±0.1	±1.0	±1.0	μA
I_{CC}	Maximum Quiescent Supply Current	V_{IN} = V_{CC} or GND	6.0V		2.0	20	40	μA
		I_{OUT} = 0 μA						

Note 4: For a power supply of 5V ±10% the worst case output voltages (V_{OH}, and V_{OL}) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC} = 5.5V and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current (I_{IN}, I_{CC}, and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0V values should be used.

AC Electrical Characteristics

V_{CC} = 5V, T_A = 25°C, C_L = 15 pF, t_r = t_f = 6 ns

Symbol	Parameter	Conditions	Typ	Guaranteed Limit	Units
t_{PHL}, t_{PLH}	Maximum Propagation Delay		12	20	ns

AC Electrical Characteristics

V_{CC} = 2.0V to 6.0V, C_L = 50 pF, t_r = t_f = 6 ns (unless otherwise specified)

Symbol	Parameter	Conditions	V_{CC}	T_A = 25°C	T_A = −40 to 85°C	T_A = −55 to 125°C	Units
				Typ	Guaranteed Limits		
t_{PHL}, t_{PLH}	Maximum Propagation Delay		2.0V	60	120	151	179	ns
			4.5V	12	24	30	36	ns
			6.0V	10	20	26	30	ns
t_{TLH}, t_{THL}	Maximum Output Rise and Fall Time		2.0V	30	75	95	110	ns
			4.5V	8	15	19	22	ns
			6.0V	7	13	16	19	ns
C_{PD}	Power Dissipation Capacitance (Note 5)	(per gate)		25				pF
C_{IN}	Maximum Input Capacitance			5	10	10	10	pF

Note 5: C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} V_{CC} f + I_{CC}$.

National Semiconductor

January 1988

MM54HC112/MM74HC112
Dual J-K Flip-Flops with Preset and Clear

General Description

These high speed (30 MHz minimum) J-K Flip-Flops utilize advanced silicon-gate CMOS technology to achieve the low power consumption and high noise immunity of standard CMOS integrated circuits, along with the ability to drive 10 LS-TTL loads.

Each flip-flop has independent J, K, PRESET, CLEAR, and CLOCK inputs and Q and $\overline{Q}$ outputs. These devices are edge sensitive to the clock input and change state on the negative going transition of the clock pulse. Clear and preset are independent of the clock and accomplished by a low logic level on the corresponding input.

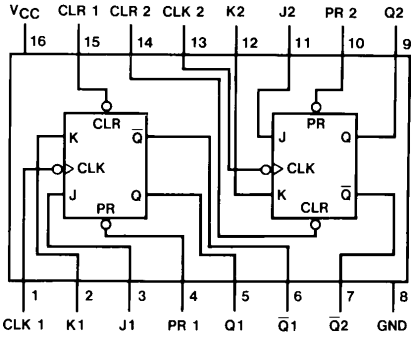
The 54HC/74HC logic family is functionally as well as pinout compatible with the standard 54LS/74LS logic family. All inputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

Features

- Typical propagation delay: 16 ns
- Wide operating voltage range
- Low input current: 1 μA maximum
- Low quiescent current: 40 μA (74HC Series)
- High output drive: 10 LS-TTL loads

Connection and Logic Diagrams

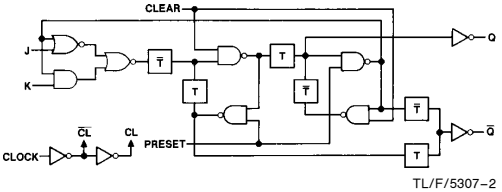
Dual-In-Line Package



TL/F/5307–1

Top View

Order Number MM54HC112 or MM74HC112

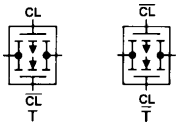


TL/F/5307–2

Truth Table

Inputs					Outputs	
PR	CLR	CLK	J	K	Q	$\overline{Q}$
L	H	X	X	X	H	L
H	L	X	X	X	L	H
L	L	X	X	X	L*	L*
H	H	↓	L	L	Q0	$\overline{Q}$0
H	H	↓	H	L	H	L
H	H	↓	L	H	L	H
H	H	↓	H	H	TOGGLE	
H	H	H	X	X	Q0	$\overline{Q}$0

*This is an unstable condition, and is not guaranteed



TL/F/5307–3

RRD-B30M105/Printed in U. S. A.

Absolute Maximum Ratings (Notes 1 & 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage (V_{CC})	−0.5 to +7.0V
DC Input Voltage (V_{IN})	−1.5 to V_{CC} +1.5V
DC Output Voltage (V_{OUT})	−0.5 to V_{CC} +0.5V
Clamp Diode Current (I_{IK}, I_{OK})	±20 mA
DC Output Current, per pin (I_{OUT})	±25 mA
DC V_{CC} or GND Current, per pin (I_{CC})	±50 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C
Power Dissipation (P_D)	
(Note 3)	600 mW
S.O. Package only	500 mW
Lead Temp. (T_L) (Soldering 10 seconds)	260°C

Operating Conditions

	Min	Max	Units
Supply Voltage (V_{CC})	2	6	V
DC Input or Output Voltage (V_{IN}, V_{OUT})	0	V_{CC}	V
Operating Temp. Range (T_A)			
MM74HC	−40	+85	°C
MM54HC	−55	+125	°C
Input Rise or Fall Times (t_r, t_f) V_{CC} = 2.0V		1000	ns
V_{CC} = 4.5V		500	ns
V_{CC} = 6.0V		400	ns

DC Electrical Characteristics (Note 4)

Symbol	Parameter	Conditions	V_{CC}	T_A = 25°C	74HC T_A = −40 to 85°C	54HC T_A = −55 to 125°C	Units
				Typ	Guaranteed Limits		
V_{IH}	Minimum High Level Input Voltage		2.0V		1.5	1.5	1.5	V
			4.5V		3.15	3.15	3.15	V
			6.0V		4.2	4.2	4.2	V
V_{IL}	Maximum Low Level Input Voltage**		2.0V		0.5	0.5	0.5	V
			4.5V		1.35	1.35	1.35	V
			6.0V		1.8	1.8	1.8	V
V_{OH}	Minimum High Level Output Voltage	V_{IN} = V_{IH} or V_{IL} $\|I_{OUT}\| \le 20\ \mu A$	2.0V	2.0	1.9	1.9	1.9	V
			4.5V	4.5	4.4	4.4	4.4	V
			6.0V	6.0	5.9	5.9	5.9	V
		V_{IN} = V_{IH} or V_{IL} $\|I_{OUT}\| \le 4.0$ mA	4.5V	4.2	3.98	3.84	3.7	V
		$\|I_{OUT}\| \le 5.2$ mA	6.0V	5.7	5.48	5.34	5.2	V
V_{OL}	Maximum Low Level Output Voltage	V_{IN} = V_{IH} or V_{IL} $\|I_{OUT}\| \le 20\ \mu A$	2.0V	0	0.1	0.1	0.1	V
			4.5V	0	0.1	0.1	0.1	V
			6.0V	0	0.1	0.1	0.1	V
		V_{IN} = V_{IH} or V_{IL} $\|I_{OUT}\| \le 4.0$ mA	4.5V	0.2	0.26	0.33	0.4	V
		$\|I_{OUT}\| \le 5.2$ mA	6.0V	0.2	0.26	0.33	0.4	V
I_{IN}	Maximum Input Current	V_{IN} = V_{CC} or GND	6.0V		±0.1	±1.0	±1.0	μA
I_{CC}	Maximum Quiescent Supply Current	V_{IN} = V_{CC} or GND I_{OUT} = 0 μA	6.0V		4.0	40	80	μA

Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: −12 mW/°C from 65°C to 85°C; ceramic "J" package: −12 mW/°C from 100°C to 125°C.

Note 4: For a power supply of 5V ±10% the worst case output voltages (V_{OH}, and V_{OL}) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC} = 5.5V and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current (I_{IN}, I_{CC}, and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0V values should be used.

**V_{IL} limits are currently tested at 20% of V_{CC}. The above V_{IL} specification (30% of V_{CC}) will be implemented no later than Q1, CY'89.

AC Electrical Characteristics $V_{CC} = 5V$, $T_A = 25°C$, $C_L = 15$ pF, $t_r = t_f = 6$ ns

Symbol	Parameter	Conditions	Typ	Guaranteed Limit	Units
f_{MAX}	Maximum Operating Frequency		50	30	MHz
t_{PHL}, t_{PLH}	Maximum Propagation Delay, Clock to Q or $\overline{Q}$		16	21	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay, Clear to Q or $\overline{Q}$		21	26	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay, Preset to Q or $\overline{Q}$		23	28	ns
t_{REM}	Minimum Removal Time, Preset or Clear to Clock		10	20	ns
t_S	Minimum Setup Time J or K to Clock		14	20	ns
t_H	Minimum Hold Time J or K from Clock		−3	0	ns
t_W	Minimum Pulse Width Clock Preset or Clear		10	16	ns

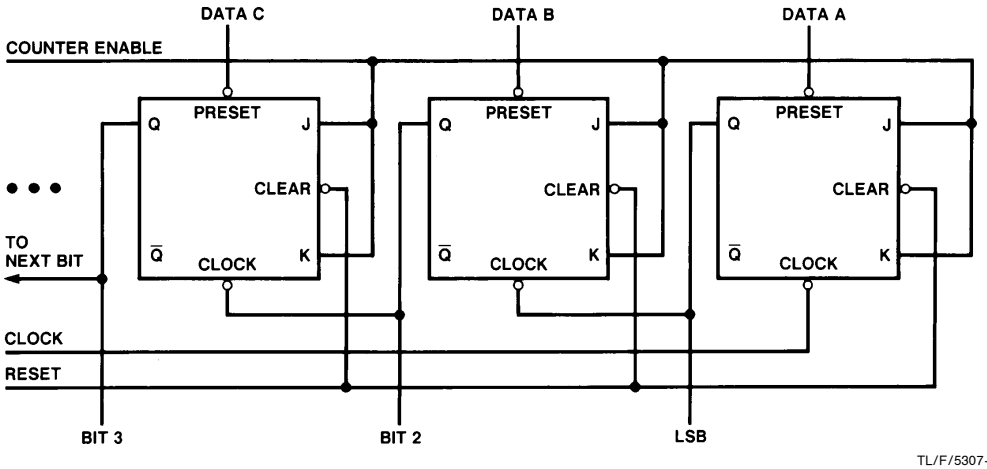
AC Electrical Characteristics $C_L = 50$ pF, $t_r = t_f = 6$ ns (unless otherwise specified)

Symbol	Parameter	Conditions	V_{CC}	$T_A = 25°C$	74HC $T_A = -40$ to $85°C$	54HC $T_A = -55$ to $125°C$	Units
				Typ	Guaranteed Limits		
f_{MAX}	Maximum Operating Frequency		2.0V	9	5	4	3	MHz
			4.5V	45	27	21	18	MHz
			6.0V	53	31	24	20	MHz
t_{PHL}, t_{PLH}	Maximum Propagation Delay, Clock to Q or $\overline{Q}$		2.0V	100	126	160	183	ns
			4.5V	20	25	32	37	ns
			6.0V	17	21	27	32	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay, Clear to Q or $\overline{Q}$		2.0V	126	155	191	250	ns
			4.5V	25	31	39	47	ns
			6.0V	21	26	33	40	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay, Preset to Q or $\overline{Q}$		2.0V	137	165	210	240	ns
			4.5V	27	33	41	50	ns
			6.0V	23	28	35	40	ns
t_{REM}	Minimum Removal Time Preset or Clear to Clock		2.0V	55	100	125	150	ns
			4.5V	11	20	25	30	ns
			6.0V	9.4	17	21	25	ns
t_S	Minimum Setup Time J or K to Clock		2.0V	77	100	125	150	ns
			4.5V	15	20	25	30	ns
			6.0V	13	17	21	25	ns
t_H	Minimum Hold Time J or K from Clock		2.0V	−3	0	0	0	ns
			4.5V	−3	0	0	0	ns
			6.0V	−3	0	0	0	ns
t_W	Minimum Pulse Width Preset, Clear or Clock		2.0V	55	80	100	120	ns
			4.5V	11	16	20	24	ns
			6.0V	9	14	18	20	ns
t_{TLH}, t_{THL}	Maximum Output Rise and Fall Time		2.0V	30	75	95	110	ns
			4.5V	8	15	19	22	ns
			6.0V	7	13	16	19	ns
t_r, t_f	Maximum Input Rise and Fall Time		2.0V		1000	1000	1000	ns
			4.5V		500	500	500	ns
			6.0V		400	400	400	ns
C_{PD}	Power Dissipation Capacitance (Note 5)	(per flip-flop)		80				pF
C_{IN}	Maximum Input Capacitance			5	10	10	10	pF

Note 5: C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} V_{CC} f + I_{CC}$.

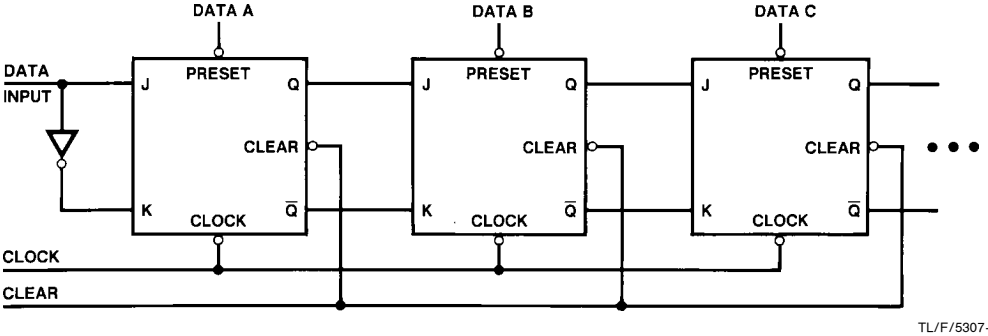
Typical Applications

N Bit Presettable Ripple Counter with Enable and Reset



TL/F/5307–4

N Bit Parallel Load/Serial Load Shift Register with Clear



TL/F/5307–5

FAIRCHILD SEMICONDUCTOR™

September 1983
Revised January 2005

MM74HC125/MM74HC126 3-STATE Quad Buffers

General Description

The MM74HC125 and MM74HC126 are general purpose 3-STATE high speed non-inverting buffers utilizing advanced silicon-gate CMOS technology. They have high drive current outputs which enable high speed operation even when driving large bus capacitances. These circuits possess the low power dissipation of CMOS circuitry, yet have speeds comparable to low power Schottky TTL circuits. Both circuits are capable of driving up to 15 low power Schottky inputs.

The MM74HC125 require the 3-STATE control input C to be taken high to put the output into the high impedance condition, whereas the MM74HC126 require the control input to be low to put the output into high impedance.

All inputs are protected from damage due to static discharge by diodes to V_{CC} and ground.

Features

- Typical propagation delay: 13 ns
- Wide operating voltage range: 2–6V
- Low input current: 1 μA maximum
- Low quiescent current: 80 μA maximum (74HC)
- Fanout of 15 LS-TTL loads

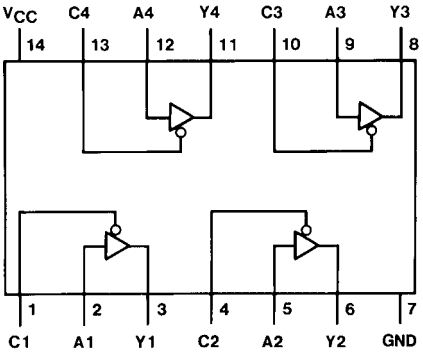
Ordering Code:

Order Number	Package Number	Package Description
MM74HC125M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC125SJ	M14D	Pb-Free 14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC125MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC125MTCX-NL		Pb-Free 14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC125N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
MM74HC126M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC126MX_NL	M14A	Pb-Free 14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC126SJ	M14D	Pb-Free 14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC126MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC126MTCX_NL	MTC14	Pb-Free 14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC126N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

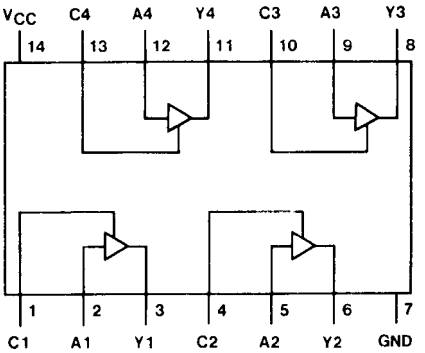
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code. (Tape and Reel not available in N14A.)
Pb-Free package per JEDEC J-STD-020B.

Connection Diagrams

Pin Assignments for DIP, SOIC, SOP and TSSOP



Top View (MM74HC125)



Top View (MM74HC126)

Truth Tables

Inputs		Output
A	C	Y
H	L	H
L	L	L
X	H	Z

Inputs		Output
A	C	Y
H	H	H
L	H	L
X	L	Z

Absolute Maximum Ratings(Note 1)

(Note 2)

Supply Voltage (V_{CC})	−0.5 to +7.0V
DC Input Voltage (V_{IN})	−1.5 to V_{CC} +1.5V
DC Output Voltage (V_{OUT})	−0.5 to V_{CC} +0.5V
Clamp Diode Current (I_{IK}, I_{OK})	±20 mA
DC Output Current, per pin (I_{OUT})	±35 mA
DC V_{CC} or GND Current, per pin (I_{CC})	±70 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C
Power Dissipation (P_D)	
(Note 3)	600 mW
S.O. Package only	500 mW
Lead Temperature (T_L)	
(Soldering 10 seconds)	260°C

Recommended Operating Conditions

	Min	Max	Units
Supply Voltage (V_{CC})	2	6	V
DC Input or Output Voltage (V_{IN}, V_{OUT})	0	V_{CC}	V
Operating Temperature Range (T_A)	−40	+85	°C
Input Rise or Fall Times (t_r, t_f)			
V_{CC} = 2.0V		1000	ns
V_{CC} = 4.5V		500	ns
V_{CC} = 6.0V		400	ns

Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: −12 mW/°C from 65°C to 85°C.

DC Electrical Characteristics (Note 4)

Symbol	Parameter	Conditions	V_{CC}	T_A = 25°C	T_A = −40 to 85°C	T_A = −40 to 125°C	Units
				Typ	Guaranteed Limits		
V_{IH}	Minimum HIGH Level Input Voltage		2.0V		1.5	1.5	1.5	V
			4.5V		3.15	3.15	3.15	V
			6.0V		4.2	4.2	4.2	V
V_{IL}	Maximum LOW Level Input Voltage		2.0V		0.5	0.5	0.5	V
			4.5V		1.35	1.35	1.35	V
			6.0V		1.8	1.8	1.8	V
V_{OH}	Minimum HIGH Level Output Voltage	V_{IN} = V_{IH} or V_{IL} $\lvert I_{OUT}\rvert \le 20\ \mu A$	2.0V	2.0	1.9	1.9	1.9	V
			4.5V	4.5	4.4	4.4	4.4	V
			6.0V	6.0	5.9	5.9	5.9	V
		V_{IN} = V_{IH} or V_{IL} $\lvert I_{OUT}\rvert \le 6.0$ mA	4.5V	4.2	3.98	3.84	3.7	V
		$\lvert I_{OUT}\rvert \le 7.8$ mA	6.0V	5.7	5.48	5.34	5.2	V
V_{OL}	Maximum LOW Level Output Voltage	V_{IN} = V_{IH} or V_{IL} $\lvert I_{OUT}\rvert \le 20\ \mu A$	2.0V	0	0.1	0.1	0.1	V
			4.5V	0	0.1	0.1	0.1	V
			6.0V	0	0.1	0.1	0.1	V
		V_{IN} = V_{IH} or V_{IL} $\lvert I_{OUT}\rvert \le 6.0$ mA	4.5V	0.2	0.26	0.33	0.4	V
		$\lvert I_{OUT}\rvert \le 7.8$ mA	6.0V	0.2	0.26	0.33	0.4	V
I_{OZ}	Maximum 3-STATE Output Leakage Current	V_{IN} = V_{IH} or V_{IL} V_{OUT} = V_{CC} or GND C_n = Disabled	6.0V		±0.5	±5	±10	μA
I_{IN}	Maximum Input Current	V_{IN} = V_{CC} or GND	6.0V		±0.1	±1.0	±1.0	μA
I_{CC}	Maximum Quiescent Supply Current	V_{IN} = V_{CC} or GND I_{OUT} = 0 μA	6.0V		8.0	80	160	μA

Note 4: For a power supply of 5V ±10% the worst case output voltages (V_{OH}, and V_{OL}) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC}=5.5V and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current (I_{IN}, I_{CC}, and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0V values should be used.

AC Electrical Characteristics

V_{CC} = 5V, T_A = 25°C, C_L = 45 pF, $t_r = t_f$ = 6 ns

Symbol	Parameter	Conditions	Typ	Guaranteed Limit	Units
t_{PHL}, t_{PLH}	Maximum Propagation Delay Time		13	18	ns
t_{PZH}	Maximum Output Enable Time to HIGH Level	R_L = 1 kΩ	13	25	ns
t_{PHZ}	Maximum Output Disable Time from HIGH Level	R_L = 1 kΩ C_L = 5 pF	17	25	ns
t_{PZL}	Maximum Output Enable Time to LOW Level	R_L = 1 kΩ	18	25	ns
t_{PLZ}	Maximum Output Disable Time from LOW Level	R_L = 1 kΩ C_L = 5 pF	13	25	ns

AC Electrical Characteristics

V_{CC} = 2.0V to 6.0V, C_L = 50 pF, $t_r = t_f$ = 6 ns (unless otherwise specified)

Symbol	Parameter	Conditions	V_{CC}	T_A = 25°C	T_A = −40 to 85°C	T_A = −40 to 125°C		Units
				Typ	Guaranteed Limits			
t_{PHL}, t_{PLH}	Maximum Propagation Delay Time		2.0V	40	100	125	150	ns
			4.5V	14	20	25	30	ns
			6.0V	12	17	21	25	ns
t_{PLH}, t_{PHL}	Maximum Propagation Delay Time	C_L = 150 pF	2.0V	35	130	163	195	ns
			4.5V	14	26	33	39	ns
			6.0V	12	22	28	39	ns
t_{PZH}, t_{PZL}	Maximum Output Enable Time	R_L = 1 kΩ	2.0V	25	125	156	188	ns
			4.5V	14	25	31	38	ns
			6.0V	12	21	26	31	ns
t_{PHZ}, t_{PLZ}	Maximum Output Disable Time	R_L = 1 kΩ	2.0V	25	125	156	188	ns
			4.5V	14	25	31	38	ns
			6.0V	12	21	26	31	ns
t_{PZL}, t_{PZH}	Maximum Output Enable Time	C_L = 150 pF	2.0V	35	140	175	210	ns
		R_L = 1 kΩ	4.5V	15	28	35	42	ns
			6.0V	13	24	30	36	ns
t_{TLH}, t_{THL}	Maximum Output Rise and Fall Time	C_L = 50 pF	2.0V	30	60	75	90	ns
			4.5V	7	12	15	18	ns
			6.0V	6	10	13	15	ns
C_{IN}	Input Capacitance			5	10	10	10	pF
C_{OUT}	Output Capacitance Outputs			15	20	20	20	pF
C_{PD}	Power Dissipation Capacitance (Note 5)	(per gate)						
		Enabled		45				pF
		Disabled		6				pF

Note 5: C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} V_{CC} f + I_{CC}$.

FAIRCHILD SEMICONDUCTOR TM

September 1983
Revised February 1999

MM74HC138
3-to-8 Line Decoder

General Description

The MM74HC138 decoder utilizes advanced silicon-gate CMOS technology and is well suited to memory address decoding or data routing applications. The circuit features high noise immunity and low power consumption usually associated with CMOS circuitry, yet has speeds comparable to low power Schottky TTL logic.

The MM74HC138 has 3 binary select inputs (A, B, and C). If the device is enabled, these inputs determine which one of the eight normally HIGH outputs will go LOW. Two active LOW and one active HIGH enables (G1, $\overline{G2A}$ and $\overline{G2B}$) are provided to ease the cascading of decoders.

The decoder's outputs can drive 10 low power Schottky TTL equivalent loads, and are functionally and pin equivalent to the 74LS138. All inputs are protected from damage due to static discharge by diodes to V_{CC} and ground.

Features

- Typical propagation delay: 20 ns
- Wide power supply range: 2V–6V
- Low quiescent current: 80 μA maximum (74HC Series)
- Low input current: 1 μA maximum
- Fanout of 10 LS-TTL loads

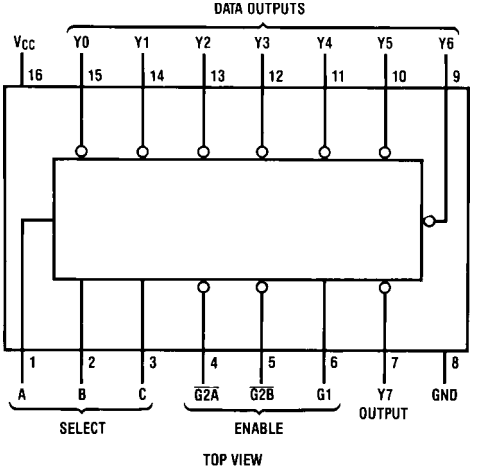
Ordering Code:

Order Number	Package Number	Package Description
MM74HC138M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC138SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC138MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC138N	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Connection Diagram

Pin Assignment for DIP, SOIC, SOP and TSSOP



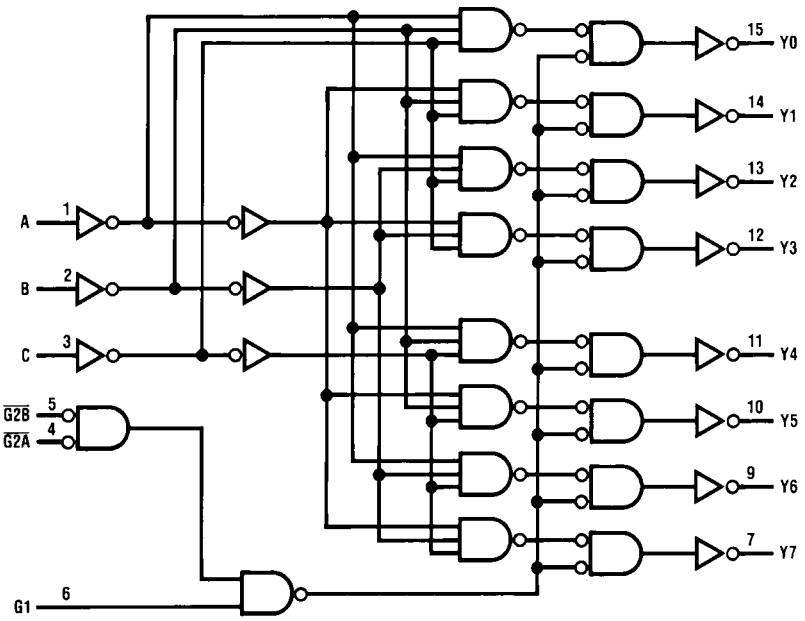
Truth Table

Inputs					Outputs							
Enable		Select										
G1	$\overline{G2}$ (Note 1)	C	B	A	Y0	Y1	Y2	Y3	Y4	Y5	Y6	Y7
X	H	X	X	X	H	H	H	H	H	H	H	H
L	X	X	X	X	H	H	H	H	H	H	H	H
H	L	L	L	L	L	H	H	H	H	H	H	H
H	L	L	L	H	H	L	H	H	H	H	H	H
H	L	L	H	L	H	H	L	H	H	H	H	H
H	L	L	H	H	H	H	H	L	H	H	H	H
H	L	H	L	L	H	H	H	H	L	H	H	H
H	L	H	L	H	H	H	H	H	H	L	H	H
H	L	H	H	L	H	H	H	H	H	H	L	H
H	L	H	H	H	H	H	H	H	H	H	H	L

H = HIGH Level, L = LOW Level, X = don't care

Note 1: $\overline{G2}$ = G2A+G2B

Logic Diagram



Absolute Maximum Ratings (Note 2)

(Note 3)

Supply Voltage (V_{CC})	− 0.5 to + 7.0V
DC Input Voltage (V_{IN})	− 1.5 to V_{CC} + 1.5V
DC Output Voltage (V_{OUT})	− 0.5 to V_{CC} + 0.5V
Clamp Diode Current (I_{IK}, I_{OK})	± 20 mA
DC Output Current, per pin (I_{OUT})	± 25 mA
DC V_{CC} or GND Current, per pin (I_{CC})	± 50 mA
Storage Temperature Range (T_{STG})	− 65°C to + 150°C
Power Dissipation (P_D)	
(Note 4)	600 mW
S.O. Package only	500 mW
Lead Temperature (T_L)	
(Soldering 10 seconds)	260°C

Recommended Operating Conditions

	Min	Max	Units
Supply Voltage (V_{CC})	2	6	V
DC Input or Output Voltage (V_{IN}, V_{OUT})	0	V_{CC}	V
Operating Temperature Range (T_A)	–40	+85	°C
Input Rise or Fall Times			
(t_r, t_f) V_{CC} = 2.0V		1000	ns
V_{CC} = 4.5V		500	ns
V_{CC} = 6.0V		400	ns

Note 2: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Note 3: Unless otherwise specified all voltages are referenced to ground.

Note 4: Power Dissipation temperature derating — plastic "N" package: – 12 mW/°C from 65°C to 85°C.

DC Electrical Characteristics (Note 5)

Symbol	Parameter	Conditions	V_{CC}	T_A = 25°C	T_A = −40 to 85°C		Units
				Typ	Guaranteed Limits		
V_{IH}	Minimum HIGH Level Input Voltage		2.0V		1.5	1.5	V
			4.5V		3.15	3.15	V
			6.0V		4.2	4.2	V
V_{IL}	Maximum LOW Level Input Voltage		2.0V		0.5	0.5	V
			4.5V		1.35	1.35	V
			6.0V		1.8	1.8	V
V_{OH}	Minimum HIGH Level Output Voltage	V_{IN} = V_{IH} or V_{IL}					
		| I_{OUT} | ≤ 20 μA	2.0V	2.0	1.9	1.9	V
			4.5V	4.5	4.4	4.4	V
			6.0V	6.0	5.9	5.9	V
		V_{IN} = V_{IH} or V_{IL}					
		| I_{OUT} | ≤ 4.0 mA	4.5V	4.2	3.98	3.84	V
		| I_{OUT} | ≤ 5.2 mA	6.0V	5.7	5.48	5.34	V
V_{OL}	Maximum LOW Level Output Voltage	V_{IN} = V_{IH} or V_{IL}					
		| I_{OUT} | ≤ 20 μA	2.0V	0	0.1	0.1	V
			4.5V	0	0.1	0.1	V
			6.0V	0	0.1	0.1	V
		V_{IN} = V_{IH} or V_{IL}					
		| I_{OUT} | ≤ 4.0 mA	4.5V	0.2	0.26	0.33	V
		| I_{OUT} | ≤ 5.2 mA	6.0V	0.2	0.26	0.33	V
I_{IN}	Maximum Input Current	V_{IN} = V_{CC} or GND	6.0V		±0.1	±1.0	μA
I_{CC}	Maximum Quiescent Supply Current	V_{IN} = V_{CC} or GND I_{OUT} = 0 μA	6.0V		8.0	80	μA

Note 5: For a power supply of 5V ± 10% the worst case output voltages (V_{OH}, and V_{OL}) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC} = 5.5V and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current (I_{IN}, I_{CC}, and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0V values should be used.

AC Electrical Characteristics

V_{CC} = 5V, T_A = 25°C, C_L = 15 pF, $t_r = t_f$ = 6 ns

Symbol	Parameter	Conditions	Typ	Guaranteed Limit	Units
t_{PLH}	Maximum Propagation Delay, Binary Select to any Output		18	25	ns
t_{PHL}	Maximum Propagation Delay, Binary Select to any Output		28	35	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay, G1 to any Output		18	25	ns
t_{PHL}	Maximum Propagation Delay $\overline{G2A}$ or $\overline{G2B}$ to Output		23	30	ns
t_{PLH}	Maximum Propagation Delay $\overline{G2A}$ or $\overline{G2B}$ to Output		18	25	ns

AC Electrical Characteristics

C_L = 50 pF, $t_r = t_f$ = 6 ns (unless otherwise specified)

Symbol	Parameter	Conditions	V_{CC}	T_A = 25°C	T_A = −40 to 85°C		Units
				Typ	Guaranteed Limits		
t_{PLH}	Maximum Propagation Delay Binary Select to any Output LOW-to-HIGH		2.0V	75	150	189	ns
			4.5V	15	30	38	ns
			6.0V	13	26	32	ns
t_{PHL}	Maximum Propagation Delay Binary Select to any Output HIGH-to-LOW		2.0V	100	200	252	ns
			4.5V	20	40	50	ns
			6.0V	17	34	43	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay G1 to any Output		2.0V	75	150	189	ns
			4.5V	15	30	38	ns
			6.0V	13	26	32	ns
t_{PHL}	Maximum Propagation Delay $\overline{G2A}$ or $\overline{G2B}$ to Output		2.0V	82	175	221	ns
			4.5V	28	35	44	ns
			6.0V	22	30	37	ns
t_{PLH}	Maximum Propagation Delay $\overline{G2A}$ or $\overline{G2B}$ to Output		2.0V	75	150	189	ns
			4.5V	15	30	38	ns
			6.0V	13	26	32	ns
t_{TLH}, t_{THL}	Output Rise and Fall Time		2.0V	30	75	95	ns
			4.5V	8	15	19	ns
			6.0V	7	13	16	ns
C_{IN}	Maximum Input Capacitance			3	10	10	pF
C_{PD}	Power Dissipation Capacitance	(Note 6)		75			pF

Note 6: C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} V_{CC} f + I_{CC}$.

National Semiconductor

November 1995

MM54HC147/MM74HC147
10-to-4 Line Priority Encoder

General Description

This high speed 10-to-4 Line Priority Encoder utilizes advanced silicon-gate CMOS technology. It possesses the high noise immunity and low power consumption of standard CMOS integrated circuits. This device is fully buffered, giving it a fanout of 10 LS-TTL loads.

The MM54HC147/MM74HC147 features priority encoding of the inputs to ensure that only the highest order data line is encoded. Nine input lines are encoded to a four line BCD output. The implied decimal zero condition requires no input condition as zero is encoded when all nine data lines are at a high logic level. All data inputs and outputs are active at the low logic level.

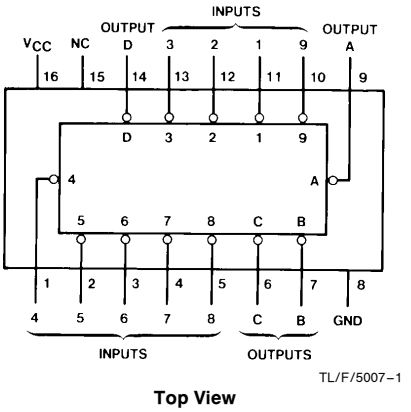
The 54HC/74HC logic family is functionally as well as pinout compatible with the standard 54LS/74LS logic family. All inputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

Features

- Low quiescent power consumption: 40 μW maximum at 25°C
- High speed: 31 ns propagation delay (typical)
- Low input current: 1 μA maximum
- Wide supply range: 2V to 6V

Connection and Logic Diagrams

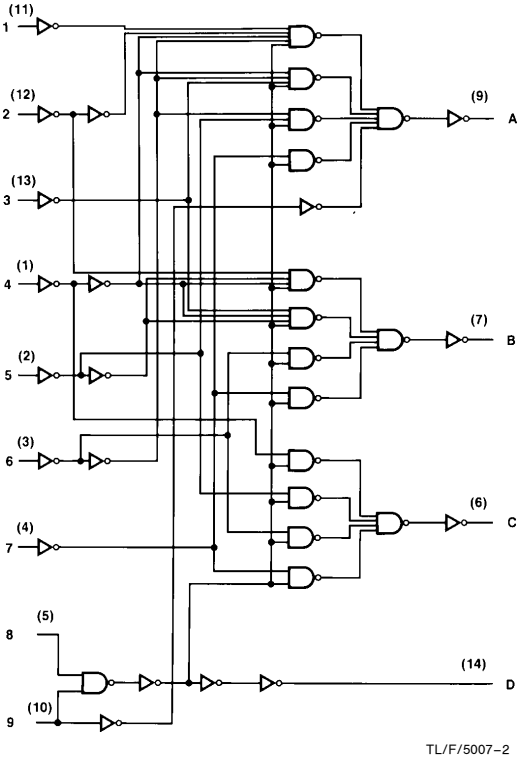
Dual-In-Line Package



TL/F/5007–1

Top View

Order Number MM54HC147 or MM74HC147



TL/F/5007–2

Truth Table

Inputs									Outputs			
1	2	3	4	5	6	7	8	9	D	C	B	A
H	H	H	H	H	H	H	H	H	H	H	H	H
X	X	X	X	X	X	X	X	L	L	H	H	L
X	X	X	X	X	X	X	L	H	L	H	H	H
X	X	X	X	X	X	L	H	H	H	L	L	L
X	X	X	X	X	L	H	H	H	H	L	L	H
X	X	X	X	L	H	H	H	H	H	L	H	L
X	X	X	L	H	H	H	H	H	H	L	H	H
X	X	L	H	H	H	H	H	H	H	H	L	L
X	L	H	H	H	H	H	H	H	H	H	L	H
L	H	H	H	H	H	H	H	H	H	H	H	L

H = High Logic Level, L = Low Logic Level, X = Irrelevant

RRD-B30M115/Printed in U. S. A.

AC Electrical Characteristics $V_{CC} = 5V$, $T_A = 25°C$, $C_L = 15$ pF, $t_r = t_f = 6$ ns

Symbol	Parameter	Conditions	Typ	Guaranteed Limit	Units
t_{PHL}, t_{PLH}	Maximum Propagation Delay		31	38	ns

AC Electrical Characteristics $V_{CC} = 2.0V$ to $6.0V$, $C_L = 50$ pF, $t_r = t_f = 6$ ns (unless otherwise specified)

Symbol	Parameter	Conditions	V_{CC}	$T_A = 25°C$		74HC $T_A = -40$ to $85°C$	54HC $T_A = -55$ to $125°C$	Units
				Typ	Guaranteed Limits			
t_{PHL}, t_{PLH}	Maximum Propagation Delay		2.0V	181	220	275	319	ns
			4.5V	36	44	55	64	ns
			6.0V	31	37	47	54	ns
t_{TLH}, t_{THL}	Maximum Output Rise and Fall Time		2.0V	30	75	95	110	ns
			4.5V	8	15	19	22	ns
			6.0V	7	13	16	19	ns
C_{PD}	Power Dissipation Capacitance (Note 5)	(per package)		180				pF
C_{IN}	Maximum Input Capacitance			5	10	10	10	pF

Note 5: C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} V_{CC} f + I_{CC}$.

National Semiconductor

January 1988

MM54HC153/MM74HC153 Dual 4-Input Multiplexer

General Description

This 4-to-1 line multiplexer utilizes advanced silicon-gate CMOS technology. It has the low power consumption and high noise immunity of standard CMOS integrated circuits. This device is fully buffered, allowing it to drive 10 LS-TTL loads. Information on the data inputs of each multiplexer is selected by the address on the A and B inputs, and is presented on the Y outputs. Each multiplexer possesses a strobe input which enables it when taken to a low logic level. When a high logic level is applied to a strobe input, the output of its associated multiplexer is taken low.

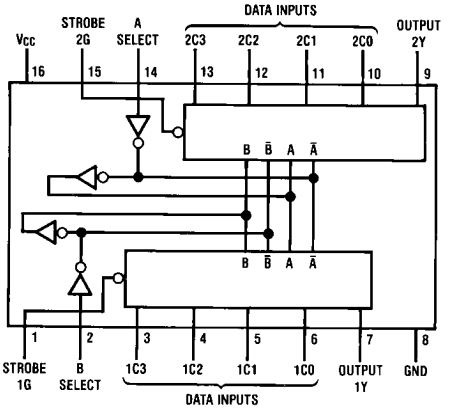
The 54HC/74HC logic family is functionally and pinout compatible with the standard 54LS/74LS logic family. All inputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

Features

- Typical propagation delay: 24 ns
- Wide power supply range: 2V–6V
- Low quiescent current: 80 μA maximum (74HC Series)
- Low input current: 1 μA maximum
- Fanout of 10 LS-TTL loads

Connection Diagram

Dual-In-Line Package



TL/F/5107–1

Top View

Order Number MM54HC153 or MM74HC153

Truth Table

Select Inputs		Data Inputs				Strobe	Output
B	A	C0	C1	C2	C3	G	Y
X	X	X	X	X	X	H	L
L	L	L	X	X	X	L	L
L	L	H	X	X	X	L	H
L	H	X	L	X	X	L	L
L	H	X	H	X	X	L	H
H	L	X	X	L	X	L	L
H	L	X	X	H	X	L	H
H	H	X	X	X	L	L	L
H	H	X	X	X	H	L	H

Select inputs A and B are common to both sections.

H = high level, L = low level, X = don't care.

 TL/F/5107 RRD-B30M105/Printed in U. S. A.

AC Electrical Characteristics $V_{CC}=5V$, $T_A=25°C$, $C_L=15$ pF, $t_r=t_f=6$ ns

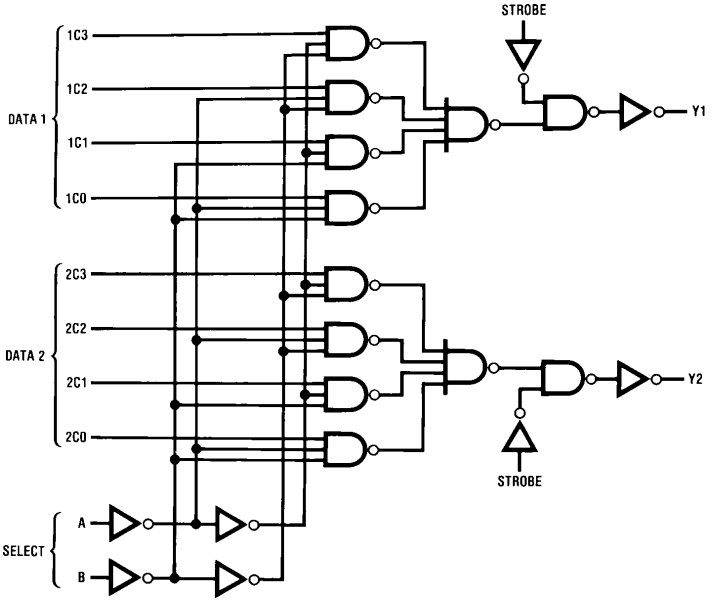
Symbol	Parameter	Conditions	Typ	Guaranteed Limit	Units
t_{PHL}, t_{PLH}	Maximum Propagation Delay, Select A or B to Y		26	30	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay, any Data to Y		20	23	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay, Strobe to Y		8	15	ns

AC Electrical Characteristics $C_L=50$ pF, $t_r=t_f=6$ ns (unless otherwise specified)

Symbol	Parameter	Conditions	V_{CC}	$T_A=25°C$	74HC $T_A=-40$ to $85°C$	54HC $T_A=-55$ to $125°C$	Units
				Typ	Guaranteed Limits		
t_{PHL}, t_{PLH}	Maximum Propagation Delay, Select A or B to Y		2.0V	131	158	198	237	ns
			4.5V	29	35	44	52	ns
			6.0V	25	30	38	45	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay, any Data to Y		2.0V	99	126	158	189	ns
			4.5V	22	28	35	42	ns
			6.0V	19	23	29	35	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay, Strobe to Y		2.0V	50	86	108	129	ns
			4.5V	12	19	24	29	ns
			6.0V	10	16	20	24	ns
t_{TLH}, t_{THL}	Maximum Output Rise and Fall Time		2.0V	30	75	95	110	ns
			4.5V	8	15	19	22	ns
			6.0V	7	13	16	19	ns
C_{IN}	Maximum Input Capacitance			5	10	10	10	pF
C_{PD}	Power Dissipation Capacitance	(Note 5)(per package)						
		Outputs Enabled		90				pF
		Outputs Disabled		25				pF

Note 5: C_{PD} determines the no load dynamic power consumption, $P_D=C_{PD}\,V_{CC}^2\,f+I_{CC}\,V_{CC}$, and the no load dynamic current consumption, $I_S=C_{PD}\,V_{CC}\,f+I_{CC}$.

Logic Diagram



TL/F/5107–2

National Semiconductor

January 1988

MM54HC155/MM74HC155 Dual 2-To-4 Line Decoder/Demultiplexers

General Description

The MM54HC155/MM74HC155 is a high speed silicon-gate CMOS decoder/demultiplexer. It utilizes advanced silicon-gate CMOS technology and features dual 1-line-to-4-line demultiplexers with independent strobes and common binary-address inputs. When both sections are enabled by the strobes, the common address inputs sequentially select and route associated input data to the appropriate output of each section. The individual strobes permit activating or inhibiting each of the 4-bit sections as desired. Data applied to input C1 is inverted at its outputs and data applied to C2 is non-inverted at its outputs. The inverter following the C1 data input permits use as a 3-to-8-line decoder, or 1-to-8-line demultiplexer, without gating.

All inputs to the decoder are protected from damage due to electrostatic discharge by diodes to V_{CC} and Ground.

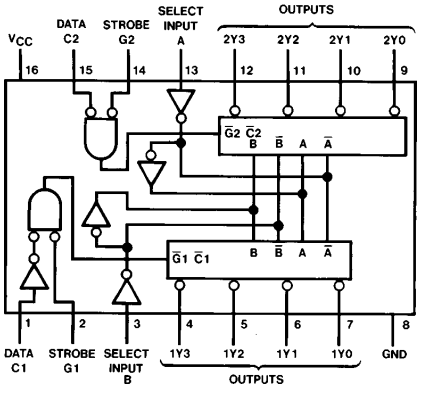
The device is capable of driving 10 low power Schottky TTL equivalent loads.

The MM54HC155/MM74HC155 is functionally and pin equivalent to the 54LS155/74LS155 with the advantage of reduced power consumption.

Features

- Applications
  - Dual 2-to-4-line decoder
  - Dual 1-to-4-line demultiplexer
  - 3-to-8-line decoder
  - 1-to-8-line demultiplexer
- Typical propagation delay: 22 ns
- Low quiescent current: 80 μA maximum (74HC series)
- Wide operating range: 2V–6V

Connect and Logic Diagram



TL/F/8364–1

Order Number MM54HC155 or MM74HC155

Truth Tables

2-to-4-Line Decoder or 1-Line to 4-line Demultiplexer

Inputs				Outputs			
Select		Strobe	Data				
B	A	G1	C1	1Y0	1Y1	1Y2	1Y3
X	X	H	X	H	H	H	H
L	L	L	H	L	H	H	H
L	H	L	H	H	L	H	H
H	L	L	H	H	H	L	H
H	H	L	H	H	H	H	L
X	X	X	L	H	H	H	H

Inputs				Outputs			
Select		Strobe	Data				
B	A	G2	C2	2Y0	2Y1	2Y2	2Y3
X	X	H	X	H	H	H	H
L	L	L	L	L	H	H	H
L	H	L	L	H	L	H	H
H	L	L	L	H	H	L	H
H	H	L	L	H	H	H	L
X	X	X	H	H	H	H	H

3-Line-to-8-Line Decoder or 1-Line-to-8-Line Demultiplexer

Inputs				Outputs							
Select			Strobe Or Data	(0)	(1)	(2)	(3)	(4)	(5)	(6)	(7)
IC	B	A	IG	2Y0	2Y1	2Y2	2Y3	1Y0	1Y1	1Y2	1Y3
X	X	X	H	H	H	H	H	H	H	H	H
L	L	L	L	L	H	H	H	H	H	H	H
L	L	H	L	H	L	H	H	H	H	H	H
L	H	L	L	H	H	L	H	H	H	H	H
L	H	H	L	H	H	H	L	H	H	H	H
H	L	L	L	H	H	H	H	L	H	H	H
H	L	H	L	H	H	H	H	H	L	H	H
H	H	L	L	H	H	H	H	H	H	L	H
H	H	H	L	H	H	H	H	H	H	H	L

IC = inputs C1 and C2 connected together
IG = inputs G1 and G2 connected together
H = high level L = low level X = don't care

RRD-B30M105/Printed in U. S. A.

AC Electrical Characteristics $V_{CC} = 5V$, $T_A = 25°C$, $C_L = 15$ pF, $t_r = t_f = 6$ ns

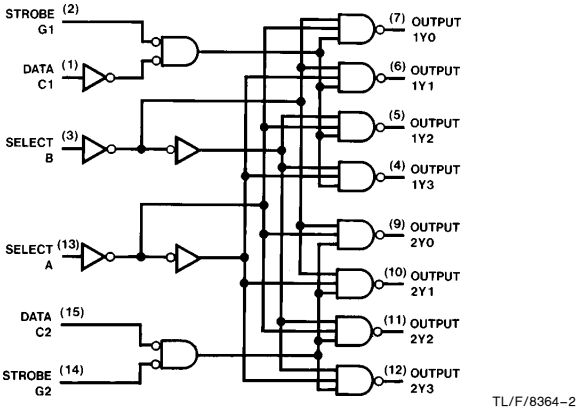
Symbol	Parameter	Conditions	Typ	Units
t_{PHL}, t_{PLH}	Maximum Propagation Delay, Binary Select to any Output 4 Levels of Delay		18	ns

AC Electrical Characteristics (Note 6) $C_L = 50$ pF, $t_r = t_f = 6$ ns (unless otherwise specified)

Symbol	Parameter	Conditions	V_{CC}	$T_A = 25°C$	74HC $T_A = -40$ to $+85°C$		54HC $T_A = -55$ to $+125°C$	Units
				Typ	Guaranteed Limits			
t_{PHL}, t_{PLH}	Maximum Propagation Delay Binary Select to any Output 4 Levels of Delay		2.0V	110	175	219	254	ns
			4.5V	22	35	44	51	ns
			6.0	18	30	38	44	ns
t_{TLH}, t_{TLH}	Maximum Output Rise and FallTime		2.0V	30	75	95	110	ns
			4.5V	8	15	19	22	ns
			6.0V	7	13	16	19	ns
C_{IN}	Maximum Input Capacitance			3	10	10	10	pF
C_{PD}	Power Dissipation Capacitance (Note 5)	(Note 5)		47				pF

Note 5: CPC determines the no load dynamic power consumption, $P_d = C_{PD} V_{CC}^2 f + I_{CC}$, and the no load dynamic current consumption, $I_S Q C_{PD} V_{CC} f + I_{CC}$.

Logic Diagram



TL/F/8364–2

FAIRCHILD SEMICONDUCTOR™

October 1987
Revised March 2002

CD4001BC/CD4011BC
Quad 2-Input NOR Buffered B Series Gate • Quad 2-Input NAND Buffered B Series Gate

General Description

The CD4001BC and CD4011BC quad gates are monolithic complementary MOS (CMOS) integrated circuits constructed with N- and P-channel enhancement mode transistors. They have equal source and sink current capabilities and conform to standard B series output drive. The devices also have buffered outputs which improve transfer characteristics by providing very high gain.

All inputs are protected against static discharge with diodes to V_{DD} and V_{SS}.

Features

- Low power TTL:
  Fan out of 2 driving 74L compatibility: or 1 driving 74LS
- 5V–10V–15V parametric ratings
- Symmetrical output characteristics
- Maximum input leakage 1 μA at 15V over full temperature range

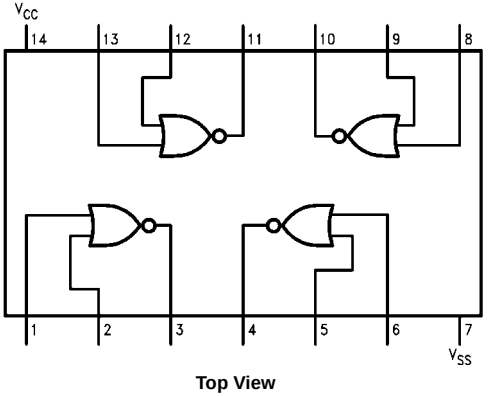
Ordering Code:

Order Number	Package Number	Package Description
CD4001BCM	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
CD4001BCSJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
CD4001BCN	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
CD4011BCM	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
CD4011BCN	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

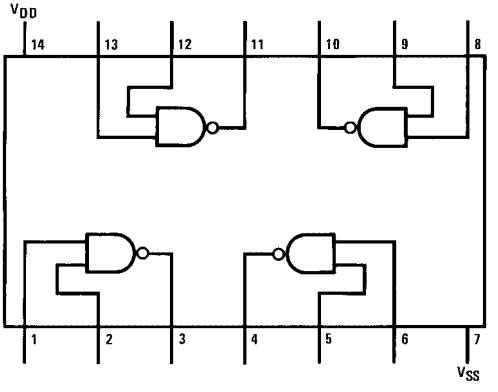
Connection Diagrams

Pin Assignments for DIP, SOIC and SOP
CD4001BC



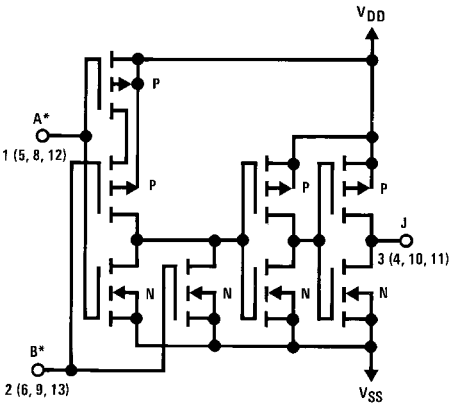
Top View

Pin Assignments for DIP and SOIC
CD4011BC

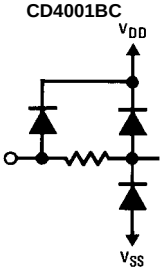


Top View

Schematic Diagrams



CD4001BC



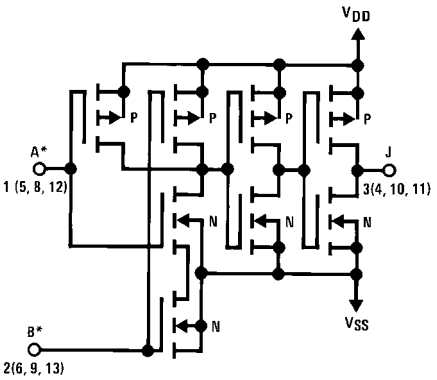
1/4 of device shown

$J = \overline{A + B}$

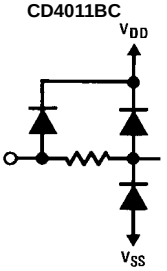
Logical "1" = HIGH

Logical "0" = LOW

All inputs protected by standard CMOS protection circuit.



CD4011BC



1/4 of device shown

$J = \overline{A \bullet B}$

Logical "1" = HIGH

Logical "0" = LOW

All inputs protected by standard CMOS protection circuit.

Absolute Maximum Ratings(Note 1)

(Note 2)

Voltage at any Pin	−0.5V to V_{DD} +0.5V
Power Dissipation (P_D)	
Dual-In-Line	700 mW
Small Outline	500 mW
V_{DD} Range	−0.5 V_{DC} to +18 V_{DC}
Storage Temperature (T_S)	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions

Operating Range (V_{DD})	3 V_{DC} to 15 V_{DC}
Operating Temperature Range	
CD4001BC, CD4011BC	−55°C to +125°C

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The Electrical Characteristics tables provide conditions for actual device operation.

Note 2: All voltages measured with respect to V_{SS} unless otherwise specified.

DC Electrical Characteristics (Note 2)

Symbol	Parameter	Conditions	−55°C		+25°C			+125°C		Units
			Min	Max	Min	Typ	Max	Min	Max	
I_{DD}	Quiescent Device Current	V_{DD} = 5V, V_{IN} = V_{DD} or V_{SS}		0.25		0.004	0.25		7.5	µA
		V_{DD} = 10V, V_{IN} = V_{DD} or V_{SS}		0.5		0.005	0.50		15	
		V_{DD} = 15V, V_{IN} = V_{DD} or V_{SS}		1.0		0.006	1.0		30	
V_{OL}	LOW Level Output Voltage	V_{DD} = 5V		0.05		0	0.05		0.05	V
		V_{DD} = 10V $\quad$ $\lvert I_O \rvert$ < 1 µA		0.05		0	0.05		0.05	
		V_{DD} = 15V		0.05		0	0.05		0.05	
V_{OH}	HIGH Level Output Voltage	V_{DD} = 5V	4.95		4.95	5		4.95		V
		V_{DD} = 10V $\quad$ $\lvert I_O \rvert$ < 1 µA	9.95		9.95	10		9.95		
		V_{DD} = 15V	14.95		14.95	15		14.95		
V_{IL}	LOW Level Input Voltage	V_{DD} = 5V, V_O = 4.5V		1.5		2	1.5		1.5	V
		V_{DD} = 10V, V_O = 9.0V		3.0		4	3.0		3.0	
		V_{DD} = 15V, V_O = 13.5V		4.0		6	4.0		4.0	
V_{IH}	HIGH Level Input Voltage	V_{DD} = 5V, V_O = 0.5V	3.5		3.5	3		3.5		V
		V_{DD} = 10V, V_O = 1.0V	7.0		7.0	6		7.0		
		V_{DD} = 15V, V_O = 1.5V	11.0		11.0	9		11.0		
I_{OL}	LOW Level Output Current (Note 3)	V_{DD} = 5V, V_O = 0.4V	0.64		0.51	0.88		0.36		mA
		V_{DD} = 10V, V_O = 0.5V	1.6		1.3	2.25		0.9		
		V_{DD} = 15V, V_O = 1.5V	4.2		3.4	8.8		2.4		
I_{OH}	HIGH Level Output Current (Note 3)	V_{DD} = 5V, V_O = 4.6V	−0.64		−0.51	−0.88		−0.36		mA
		V_{DD} = 10V, V_O = 9.5V	−1.6		−1.3	−2.25		−0.9		
		V_{DD} = 15V, V_O = 13.5V	−4.2		−3.4	−8.8		−2.4		
I_{IN}	Input Current	V_{DD} = 15V, V_{IN} = 0V		−0.10		-10^{-5}	−0.10		−1.0	µA
		V_{DD} = 15V, V_{IN} = 15V		0.1		10^{-5}	0.10		1.0	

Note 3: I_{OL} and I_{OH} are tested one output at a time.

AC Electrical Characteristics (Note 4)

CD4001BC: T_A = 25°C, Input t_r; t_f = 20 ns. C_L = 50 pF, R_L = 200k. Typical temperature coefficient is 0.3%/°C.

Symbol	Parameter	Conditions	Typ	Max	Units
t_{PHL}	Propagation Delay Time, HIGH-to-LOW Level	V_{DD} = 5V	120	250	ns
		V_{DD} = 10V	50	100	
		V_{DD} = 15V	35	70	
t_{PLH}	Propagation Delay Time, LOW-to-HIGH Level	V_{DD} = 5V	110	250	ns
		V_{DD} = 10V	50	100	
		V_{DD} = 15V	35	70	
t_{THL}, t_{TLH}	Transition Time	V_{DD} = 5V	90	200	ns
		V_{DD} = 10V	50	100	
		V_{DD} = 15V	40	80	
C_{IN}	Average Input Capacitance	Any Input	5	7.5	pF
C_{PD}	Power Dissipation Capacity	Any Gate	14		pF

Note 4: AC Parameters are guaranteed by DC correlated testing.

AC Electrical Characteristics (Note 5)

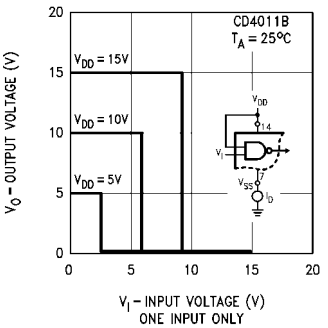
CD4011BC: T_A= 25°C, Input t_r; t_f = 20 ns. C_L = 50 pF, R_L = 200k. Typical Temperature Coefficient is 0.3%/°C.

Symbol	Parameter	Conditions	Typ	Max	Units
t_{PHL}	Propagation Delay,	V_{DD} = 5V	120	250	
	HIGH-to-LOW Level	V_{DD} = 10V	50	100	ns
		V_{DD} = 15V	35	70	
t_{PLH}	Propagation Delay,	V_{DD} = 5V	85	250	
	LOW-to-HIGH Level	V_{DD} = 10V	40	100	ns
		V_{DD} = 15V	30	70	
t_{THL}, t_{TLH}	Transition Time	V_{DD} = 5V	90	200	
		V_{DD} = 10V	50	100	ns
		V_{DD} = 15V	40	80	
C_{IN}	Average Input Capacitance	Any Input	5	7.5	pF
C_{PD}	Power Dissipation Capacity	Any Gate	14		pF

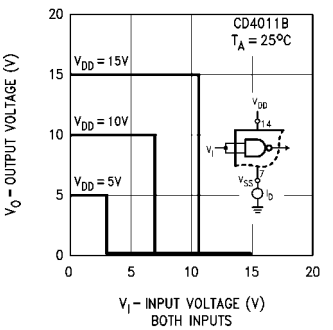
Note 5: AC Parameters are guaranteed by DC correlated testing.

Typical Performance Characteristics

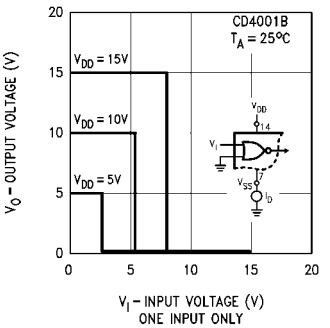
Typical Transfer Characteristics



Typical Transfer Characteristics

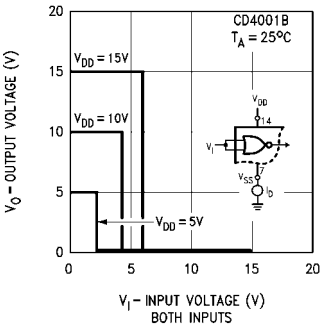


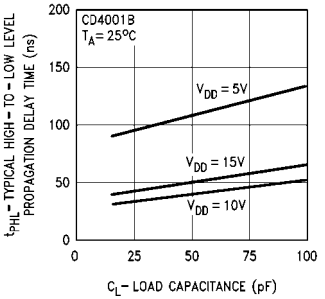
Typical Transfer Characteristics

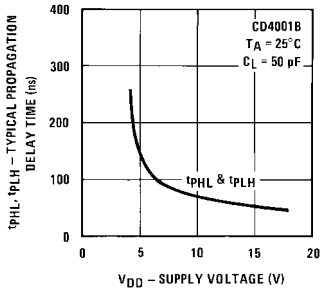


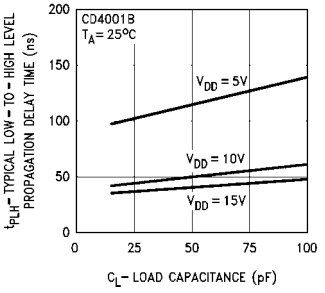
Typical Performance Characteristics (Continued)

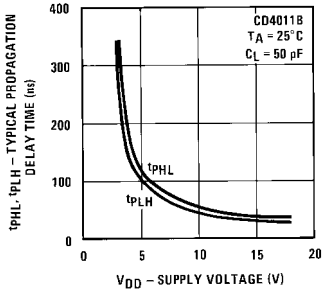
Typical Transfer Characteristics

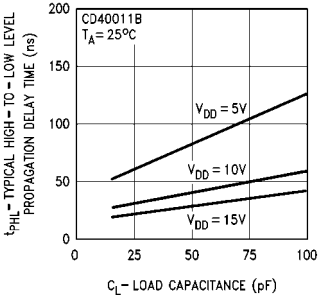




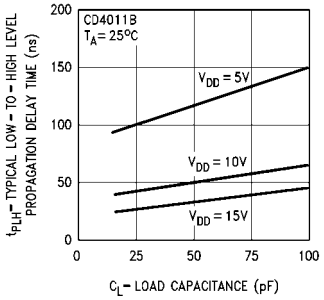


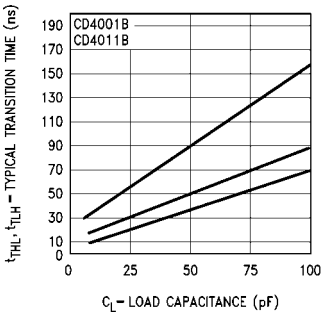


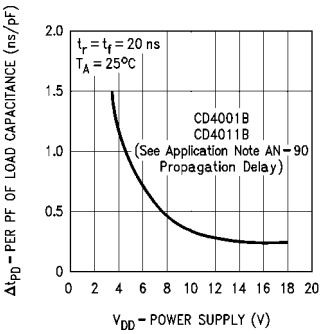


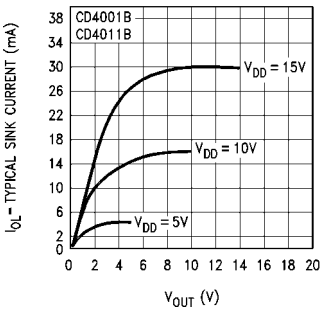


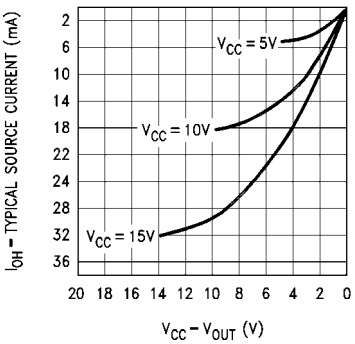
Typical Performance Characteristics (Continued)











FAIRCHILD SEMICONDUCTOR™

November 1983
Revised March 2002

CD4016BC
Quad Bilateral Switch

General Description

The CD4016BC is a quad bilateral switch intended for the transmission or multiplexing of analog or digital signals. It is pin-for-pin compatible with CD4066BC.

Features

- Wide supply voltage range: 3V to 15V
- Wide range of digital and analog switching: ±7.5 V_{PEAK}
- "ON" Resistance for 15V operation: 400Ω (typ)
- Matched "ON" Resistance over 15V signal input:
  ΔR_{ON} = 10Ω (typ)
- High degree of linearity:
  0.4% distortion (typ)
  @ f_{IS} = 1 kHz, V_{IS} = 5 V_{p-p},
  V_{DD}–V_{SS} = 10V, R_L = 10 kΩ
- Extremely low "OFF" switch leakage:
  0.1 nA (typ.)
  @ $V_{DD} - V_{SS}$ = 10V
  T_A = 25°C
- Extremely high control input impedance: 10^{12}Ω (typ)
- Low crosstalk between switches:
  –50 dB (typ.)
  @ f_{IS} = 0.9 MHz, R_L = 1 kΩ
- Frequency response, switch "ON": 40 MHz (typ)

Applications

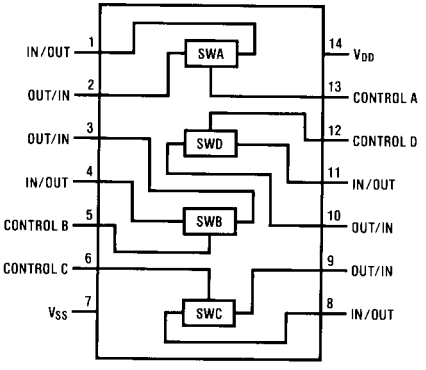
- Analog signal switching/multiplexing
  - Signal gating
  - Squelch control
  - Chopper
  - Modulator/Demodulator
  - Commutating switch
- Digital signal switching/multiplexing
- CMOS logic implementation
- Analog-to-digital/digital-to-analog conversion
- Digital control of frequency, impedance, phase, and analog-signal gain

Ordering Code:

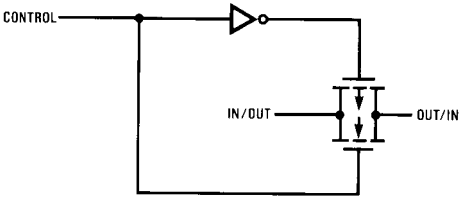
Order Number	Package Number	Package Description
CD4016BCM	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
CD4016BCN	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices also available in Tape and Reel. Specify by appending the letter suffix "X" to the ordering code.

Connection Diagram



Schematic Diagram



Absolute Maximum Ratings (Note 1)

(Note 2)

V_{DD} Supply Voltage	−0.5V to +18V
V_{IN} Input Voltage	−0.5V to V_{DD} + 0.5V
T_S Storage Temperature Range	−65°C to + 150°C
Power Dissipation (P_D)	
Dual-In-Line	700 mW
Small Outline	500 mW
Lead Temperature	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 2)

V_{DD} Supply Voltage	3V to 15V
V_{IN} Input Voltage	0V to V_{DD}
T_A Operating Temperature Range	−55°C to +125°C

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The tables of "Recommended Operating Conditions" and "Electrical Characteristics" provide conditions for actual device operation.

Note 2: V_{SS} = 0V unless otherwise specified.

DC Electrical Characteristics (Note 2)

Symbol	Parameter	Conditions	−55°C		25°C			+125°C		Units
			Min	Max	Min	Typ	Max	Min	Max	
I_{DD}	Quiescent Device Current	V_{DD} = 5V, V_{IN} = V_{DD} or V_{SS}		0.25		0.01	0.25		7.5	µA
		V_{DD} = 10V, V_{IN} = V_{DD} or V_{SS}		0.5		0.01	0.5		15	µA
		V_{DD} = 15V, V_{IN} = V_{DD} or V_{SS}		1.0		0.01	1.0		30	µA
Signal Inputs and Outputs										
R_{ON}	"ON" Resistance	R_L = 10kΩ to (V_{DD} − V_{SS})/2								
		V_C = V_{DD}, V_{IS} = V_{SS} or V_{DD}								
		V_{DD} = 10V		600		250	660		960	Ω
		V_{DD} = 15V		360		200	400		600	Ω
		R_L = 10kΩ to (V_{DD} − V_{SS})/2								
		V_C = V_{DD}								
		V_{DD} = 10V, V_{IS} = 4.75 to 5.25V		1870		850	2000		2600	Ω
		V_{DD} = 15V, V_{IS} = 7.25 to 7.75V		775		400	850		1230	Ω
ΔR_{ON}	Δ"ON" Resistance	R_L = 10kΩ to (V_{DD} − V_{SS})/2								
	Between any 2 of	V_C = V_{DD}, V_{IS} = V_{SS} to V_{DD}								
	4 Switches	V_{DD} = 10V				15				Ω
	(In Same Package)	V_{DD} = 15V				10				Ω
I_{IS}	Input or Output Leakage	V_C = 0, V_{DD} = 15V		±50		±0.1	±50		±500	nA
		V_{IS} = 0V or 15V,								
	Switch "OFF"	V_{OS} = 15V or 0V								
Control Inputs										
V_{ILC}	LOW Level Input Voltage	V_{IS} = V_{SS} and V_{DD}								
		V_{OS} = V_{DD} and V_{SS}								
		I_{IS} = ±10 µA								
		V_{DD} = 5V		0.9			0.7		0.5	V
		V_{DD} = 10V		0.9			0.7		0.5	V
		V_{DD} = 15V		0.9			0.7		0.5	V
V_{IHC}	HIGH Level Input Voltage	V_{DD} = 5V	3.5		3.5			3.5		V
		V_{DD} = 10V	7.0		7.0			7.0		V
		V_{DD} = 15V	11.0		11.0			11.0		V
		(Note 3) and Table 1								
I_{IN}	Input Current	V_{CC} − V_{SS} = 15V		±0.1		$\pm 10^{-5}$	±0.1		±1.0	µA
		$V_{DD} \geq V_{IS} \geq V_{SS}$								
		$V_{DD} \geq V_C \geq V_{SS}$								

Note 3: If the switch input is held at V_{DD}, V_{IHC} is the control input level that will cause the switch output to meet the standard "B" series V_{OH} and I_{OH} output levels. If the analog switch input is connected to V_{SS}, V_{IHC} is the control input level — which allows the switch to sink standard "B" series $|I_{OH}|$, HIGH level current, and still maintain a $V_{OL} \leq$ "B" series. These currents are shown in Table 1.

AC Electrical Characteristics (Note 4)

$T_A = 25°C$, $t_r = t_f = 20$ ns and $V_{SS} = 0V$ unless otherwise specified

Symbol	Parameter	Conditions	Min	Typ	Max	Units
t_{PHL}, t_{PLH}	Propagation Delay Time	$V_C = V_{DD}$, $C_L = 50$ pF, (Figure 1)				
	Signal Input to Signal Output	$R_L = 200k$				
		$V_{DD} = 5V$		58	100	ns
		$V_{DD} = 10V$		27	50	ns
		$V_{DD} = 15V$		20	40	ns
t_{PZH}, t_{PZL}	Propagation Delay Time	$R_L = 1.0$ kΩ, $C_L = 50$ pF, (Figure 2, Figure 3)				
	Control Input to Signal	$V_{DD} = 5V$		20	50	ns
	Output HIGH Impedance to	$V_{DD} = 10V$		18	40	ns
	Logical Level	$V_{DD} = 15V$		17	35	ns
t_{PHZ}, t_{PLZ}	Propagation Delay Time	$R_L = 1.0$ kΩ, $C_L = 50$ pF, (Figure 2, Figure 3)				
	Control Input to Signal	$V_{DD} = 5V$		15	40	ns
	Output Logical Level to	$V_{DD} = 10V$		11	25	ns
	HIGH Impedance	$V_{DD} = 15V$		10	22	ns
	Sine Wave Distortion	$V_C = V_{DD} = 5V$, $V_{SS} = -5$		0.4		%
		$R_L = 10$ kΩ, $V_{IS} = 5\ V_{P-P}$, f = 1 kHz,				
		(Figure 4)				
	Frequency Response — Switch	$V_C = V_{DD} = 5V$, $V_{SS} = -5V$,		40		MHz
	"ON" (Frequency at −3 dB)	$R_L = 1$ kΩ, $V_{IS} = 5\ V_{P-P}$,				
		$20\ \text{Log}_{10}\ V_{OS}/V_{OS}$ (1 kHz) −dB,				
		(Figure 4)				
	Feedthrough — Switch "OFF"	$V_{DD} = 5V$, $V_C = V_{SS} = -5V$,		1.25		MHz
	(Frequency at −50 dB)	$R_L = 1$ kΩ, $V_{IS} = 5\ V_{P-P}$,				
		$20\ \text{Log}_{10}\ (V_{OS}/V_{IS}) = -50$ dB,				
		(Figure 4)				
	Crosstalk Between Any Two	$V_{DD} = V_{C(A)} = 5V$; $V_{SS} = V_{C(B)} = -5V$,		0.9		MHz
	Switches (Frequency at −50 dB)	$R_L = 1$ kΩ$V_{IS(A)} = 5\ V_{P-P}$,				
		$20\ \text{Log}_{10}\ (V_{OS(B)}/V_{OS(A)}) = -50$ dB,				
		(Figure 5)				
	Crosstalk; Control Input to	$V_{DD} = 10V$, $R_L = 10$ kΩ		150		mV_{P-P}
	Signal Output	$R_{IN} = 1$ kΩ, $V_{CC} = 10V$ Square Wave,				
		$C_L = 50$ pF (Figure 6)				
	Maximum Control Input	$R_L = 1$ kΩ, $C_L = 50$ pF, (Figure 7)				
		$V_{OS(f)} = ½\ V_{OS}$(1 kHz)				
		$V_{DD} = 5V$		6.5		MHz
		$V_{DD} = 10V$		8.0		MHz
		$V_{DD} = 15V$		9.0		MHz
C_{IS}	Signal Input Capacitance			4		pF
C_{OS}	Signal Output Capacitance	$V_{DD} = 10V$		4		pF
C_{IOS}	Feedthrough Capacitance	$V_C = 0V$		0.2		pF
C_{IN}	Control Input Capacitance			5	7.5	pF

Note 4: AC Parameters are guaranteed by DC correlated testing.

Note 5: These devices should not be connected to circuits with the power "ON".

Note 6: In all cases, there is approximately 5 pF of probe and jig capacitance on the output; however, this capacitance is included in C_L wherever it is specified.

Note 7: V_{IS} is the voltage at the in/out pin and V_{OS} is the voltage at the out/in pin. V_C is the voltage at the control input.

AC Test Circuits and Switching Time Waveforms

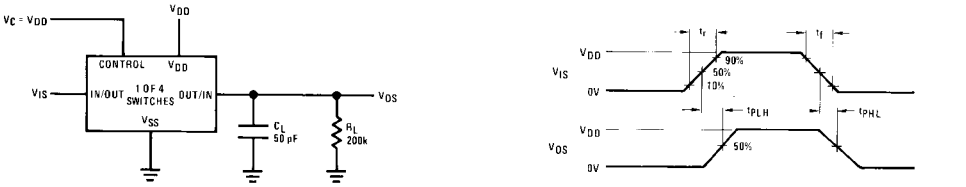


FIGURE 1. t_{PLH}, t_{PLH} Propagation Delay Time Control to Signal Output

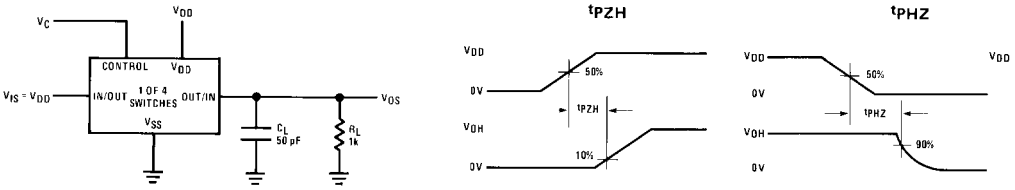


FIGURE 2. t_{PZH}, t_{PHZ} Propagation Delay Time Control to Signal Output

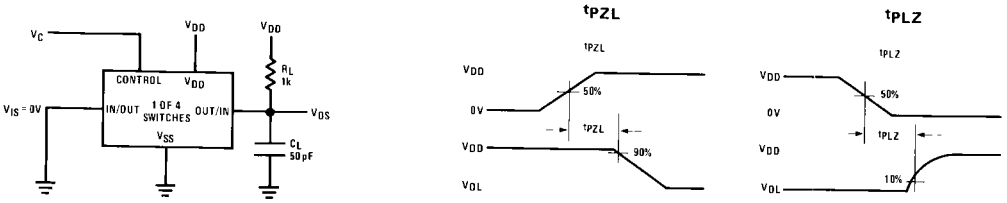
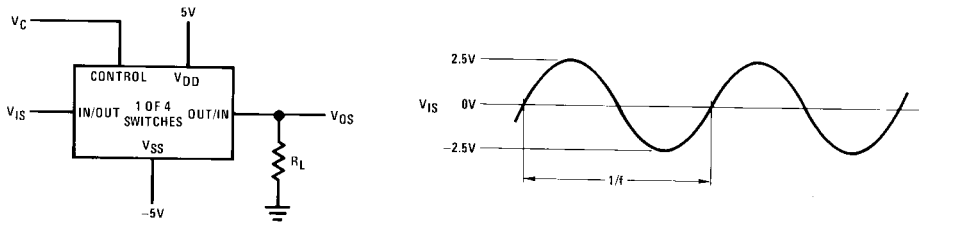


FIGURE 3. t_{PZH}, t_{PHZ} Propagation Delay Time Control to Signal Output



$V_C = V_{DD}$ for distortion and frequency response tests

$V_C = V_{SS}$ for feedthrough test

FIGURE 4. Sine Wave Distortion, Frequency Response and Feedthrough

AC Test Circuits and Switching Time Waveforms (Continued)

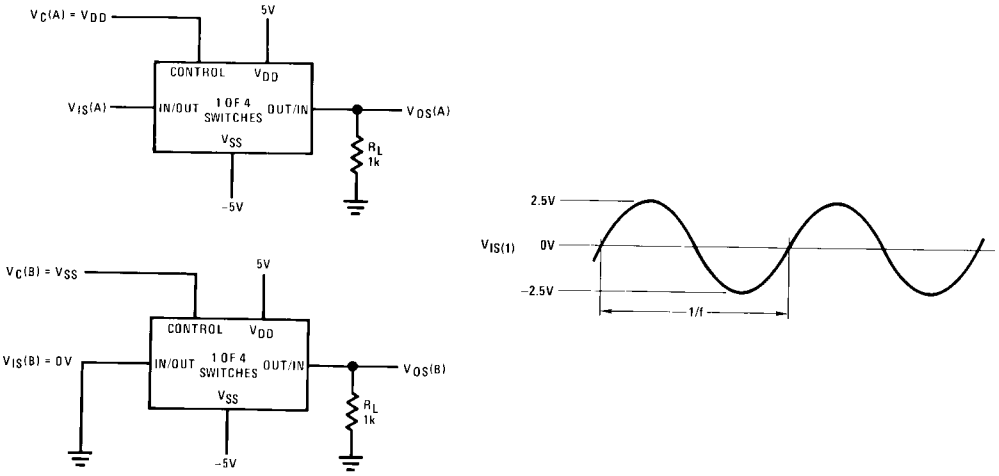


FIGURE 5. Crosstalk Between Any Two Switches

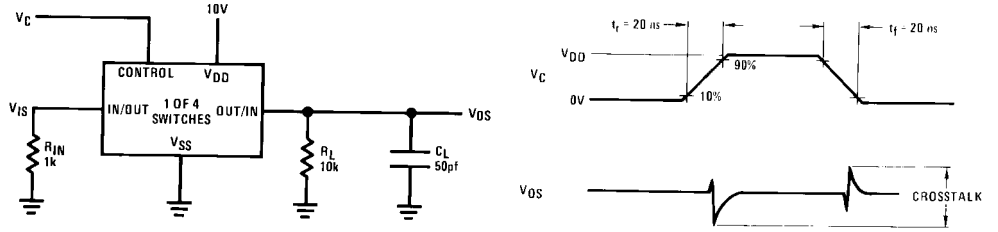


FIGURE 6. Crosstalk — Control to Input Signal Output

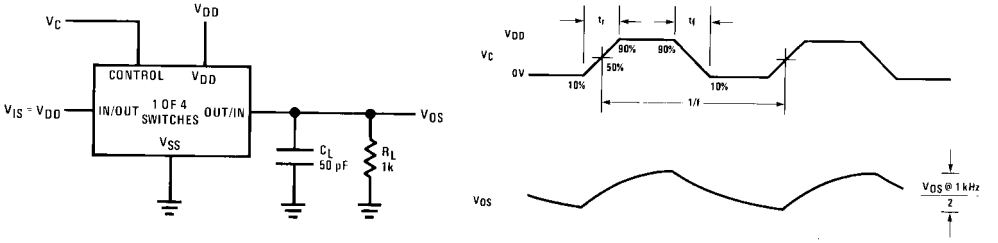


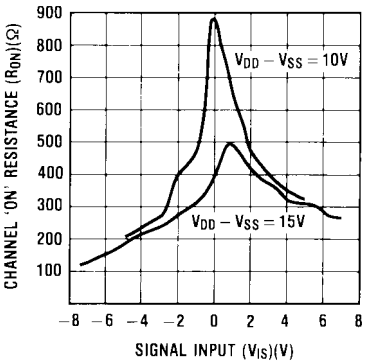
FIGURE 7. Maximum Control Input Frequency

TABLE 1. CD4016B Switch Test Conditions for V_{IHC}

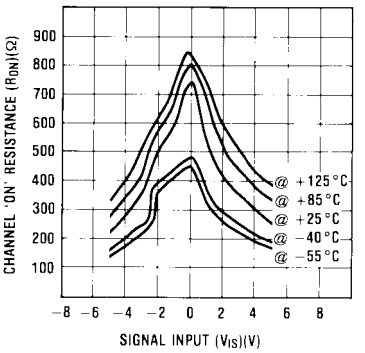
Temperature Range	V_{DD}	Switch Input				Switch Output	
		V_{IS}	I_{IS} (mA)			V_{OS}(V)	
			−40°C	25°C	+85°C	Min	Max
COMMERCIAL	5	0	0.2	0.16	0.12		0.4
	5	5	−0.2	−0.16	−0.12	4.6	
	10	0	0.5	0.4	0.3		0.5
	10	10	−0.5	−0.4	−0.3	9.5	
	15	0	1.4	1.2	1.0		1.5
	15	15	−1.4	−1.2	−1.0	13.5	

Typical Performance Characteristics

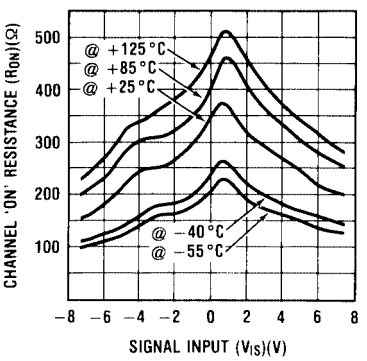
'ON' Resistance vs. Signal Voltage T_A = 25°C



'ON' Resistance Temperature Variation for $V_{DD} - V_{SS}$ = 10V



'ON' Resistance Temperature Variation for $V_{DD} - V_{SS}$ = 15V



High Intensity Red Low Current Seven Segment Display

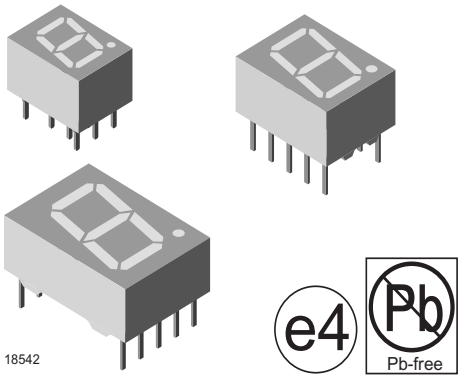
Description

This series defines a new standard for Low Current Displays. It is a single digit 7-Segment LED display utilizing AlInGaP technology in color red.

The supreme light intensity allows applications under direct sunlight or "black front" designs by using tinted filter glass in front of the display.

Typical 1500 µcd at 1.0 mA is Best in Class Performance for applications with very limited power supply. The maximum forward current of 10 mA is allowed for an ambient temperature range of - 40° to +85° C without current derating.

Crosstalk between segments is possible at drive currents above 5 mA per segment. Therefore it is recommend to apply more than 5 mA only under direct sunlight or with tinted filter glass.



Features

- 1500 µcd typical at 1.0 mA
- Very low power consumption
- Wide viewing angle
- Grey package surface
- Light intensity categorized at I_F= 1.0mA
- Lead-free device

Applications

Battery driven instruments
Telecom devices
Home appliances
Instrumentation
POS Terminals

Parts Table

Part	Color, Luminous Intensity	Circuitry
TDSR0750	High intensity low current red	Common anode
TDSR0760	High intensity low current red	Common cathode
TDSR1050	High intensity low current red	Common anode
TDSR1060	High intensity low current red	Common cathode
TDSR1350	High intensity low current red	Common anode
TDSR1360	High intensity low current red	Common cathode

Absolute Maximum Ratings

T_{amb} = 25 °C, unless otherwise specified
TDSR0750/0760 , TDSR1050/1060 , TDSR1350/1360

Parameter	Test condition	Symbol	Value	Unit
Reverse voltage per segment		V_R	5	V
DC Forward current per segment		I_F	10	mA
Peak forward current per segment	$t_p \leq 10$ µs, duty cycle 1/10	I_{FM}	50	mA

Parameter	Test condition	Symbol	Value	Unit
Power dissipation	$T_{amb} \leq 85°C$	P_V	185	mW
Junction temperature		T_j	105	°C
Operating temperature range		T_{amb}	- 40 to + 85	°C
Storage temperature range		T_{stg}	- 40 to + 85	°C
Soldering temperature	t ≤ 3 sec, 2mm below seating plane	T_{sd}	260	°C
Thermal resistance LED junction/ambient		R_{thJA}	100	K/W

Optical and Electrical Characteristics

T_{amb} = 25 °C, unless otherwise specified

Red

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
TDSR0750, TDSR0760						
Luminous intensity per segment (digit average)	I_F = 1 mA	I_V	180		2200	µcd
Dominant wavelength	I_F = 1 mA	λ_d		640		nm
Peak wavelength	I_F = 1 mA	λ_p		650		nm
Forward voltage per segment or DP	I_F = 1 mA	V_F		1.8	2.4	V
Reverse voltage per segment or DP	V_R = 6 V	I_R		10		µA
TDSR1050, TDSR1060						
Luminous intensity per segment (digit average)	I_F = 1 mA	I_V	280		3600	µcd
Dominant wavelength	I_F = 1 mA	λ_d		640		nm
Peak wavelength	I_F = 1 mA	λ_p		650		nm
Forward voltage per segment or DP	I_F = 1 mA	V_F		1.8	2.4	V
Reverse voltage per segment or DP	V_R = 6 V	I_R		10		µA
TDSR1350, TDSR1360						
Luminous intensity per segment (digit average)	I_F = 1 mA	I_V	280		3600	µcd
Dominant wavelength	I_F = 1 mA	λ_d		640		nm
Peak wavelength	I_F = 1 mA	λ_p		650		nm
Forward voltage per segment or DP	I_F = 1 mA	V_F		1.8	2.4	V
Reverse voltage per segment or DP	V_R = 6 V	I_R		10		µA

Typical Characteristics (T_{amb} = 25 °C unless otherwise specified)

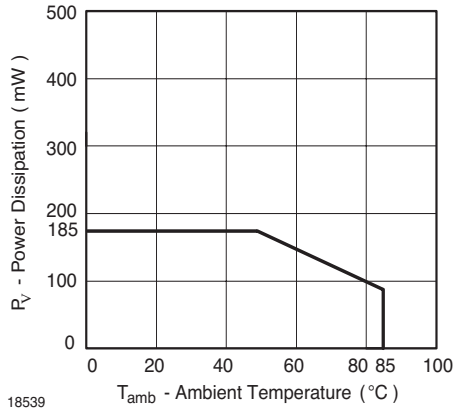


Figure 1. Power Dissipation vs. Ambient Temperature

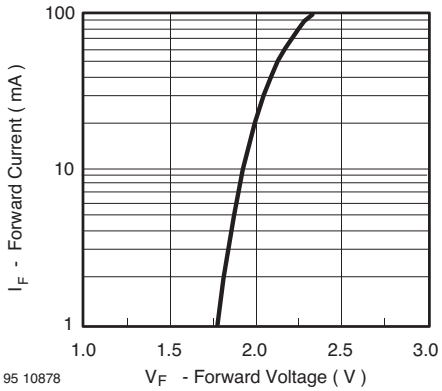


Figure 4. Forward Current vs. Forward Voltage

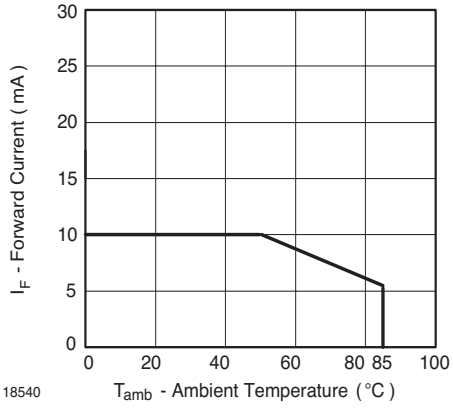


Figure 2. Forward Current vs. Ambient Temperature

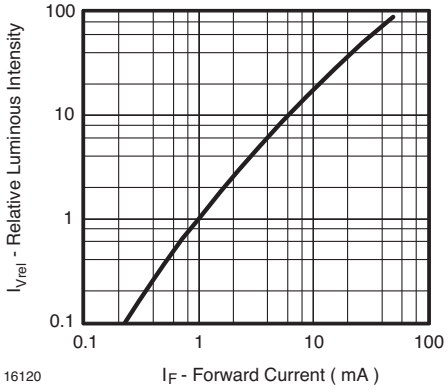


Figure 5. Relative Luminous Intensity vs. Forward Current

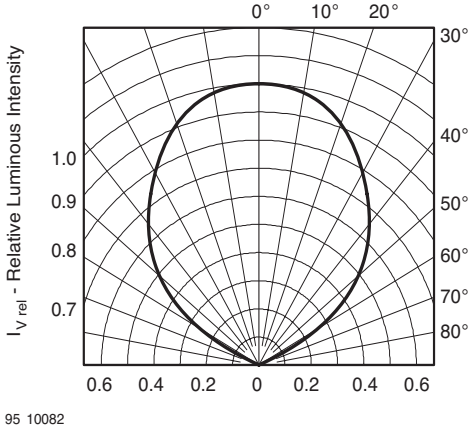


Figure 3. Rel. Luminous Intensity vs. Angular Displacement

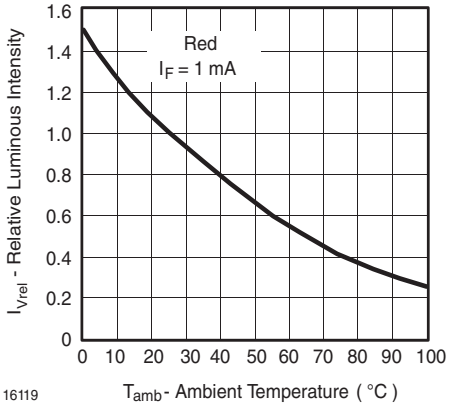


Figure 6. Rel. Luminous Intensity vs. Ambient Temperature

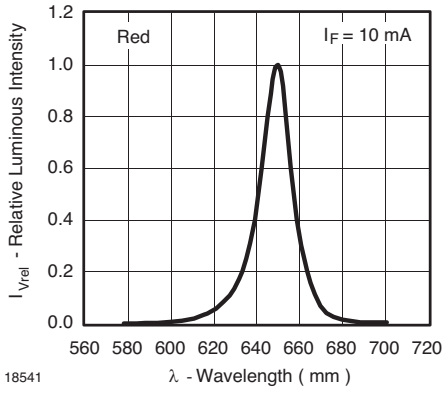
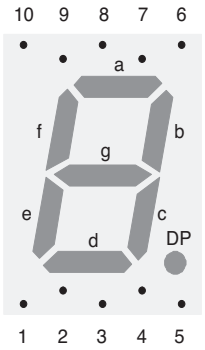
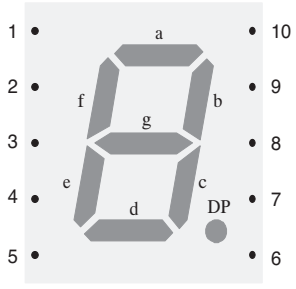


Figure 7. Rel. Luminous Intensity vs. Ambient Temperature



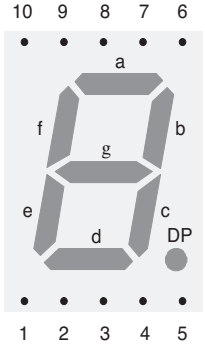
1	e
2	d
3	A (C)
4	c
5	DP
6	b
7	a
8	A (C)
9	g
10	f

96 11677



1	g
2	f
3	A (C)
4	e
5	d
6	DP
7	c
8	A (C)
9	b
10	a

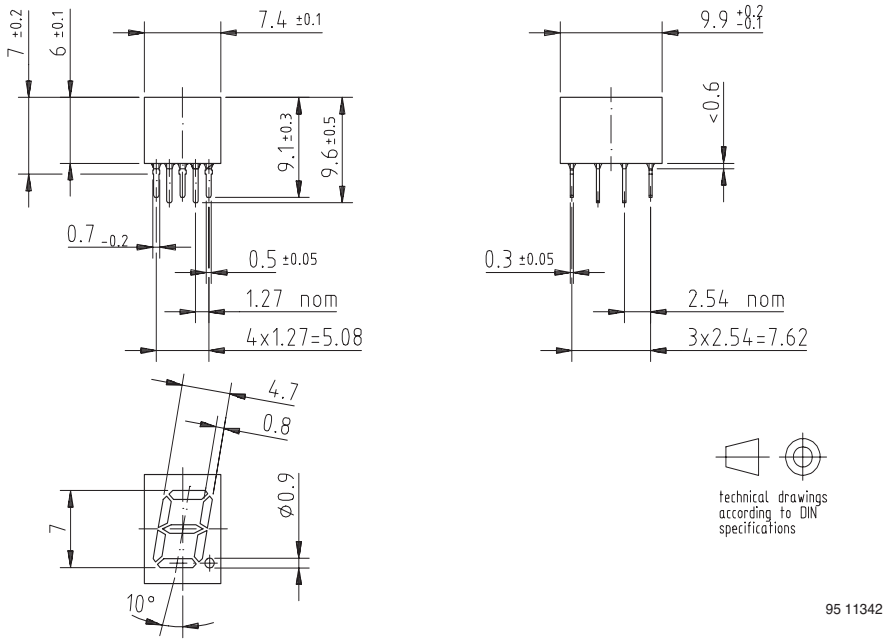
96 11678



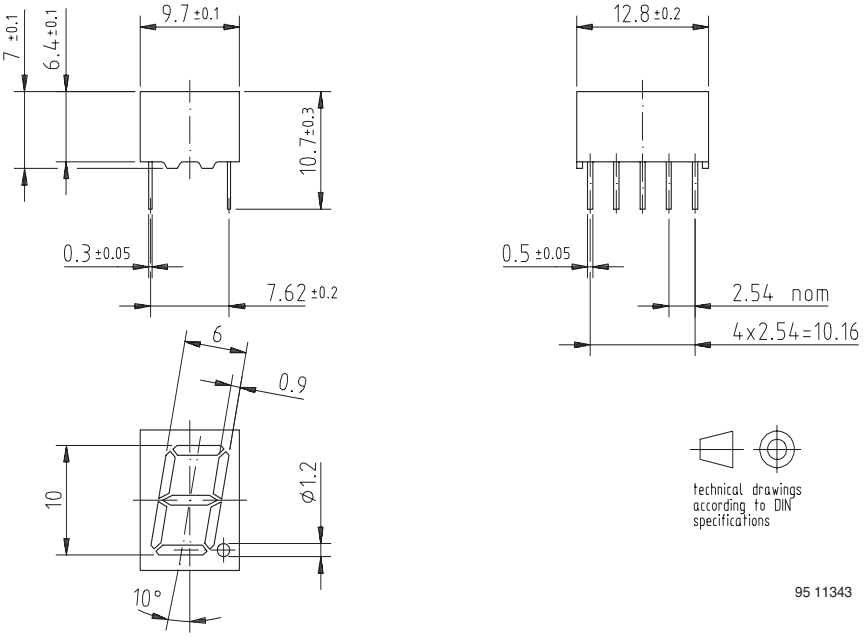
1	e
2	d
3	A (C)
4	c
5	DP
6	b
7	a
8	A (C)
9	f
10	g

95 10896

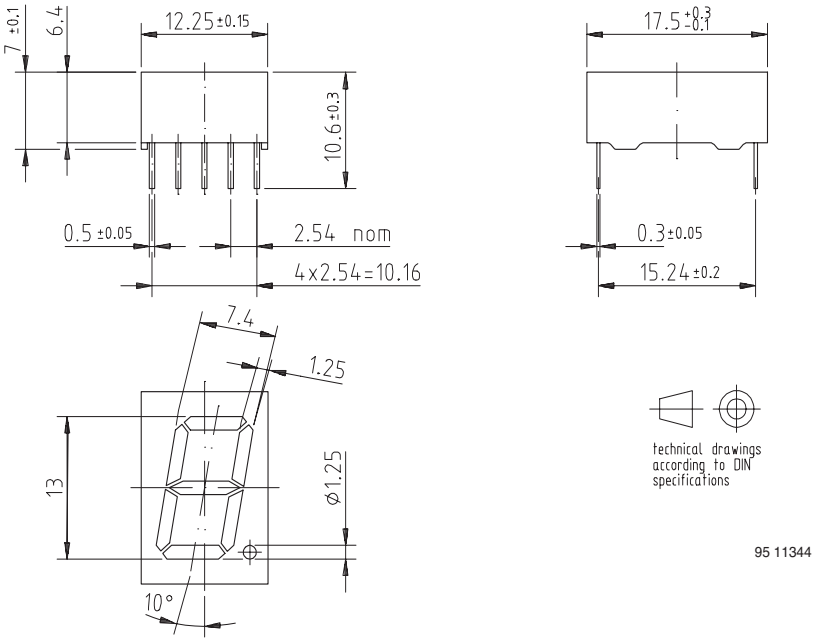
Package Dimensions in mm

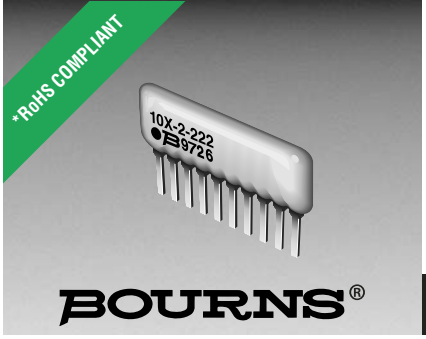


Package Dimensions in mm



Package Dimensions in mm





Features

- RoHS compliant*)
- Low profile is compatible with DIPs
- Wide assortment of pin packages enhances design flexibility
- Ammo-pak packaging available
- Recommended for rosin flux and solvent clean or no clean flux processes
- Marking on contrasting background for permanent identification

4600X Series - Thick Film Conformal SIPs

Product Characteristics

Resistance Range
.....10 ohms to 10 megohms
Maximum Operating Voltage.....100 V
Temperature Coefficient of Resistance
50 Ω to 2.2 MΩ.....±100 ppm/°C
below 50 Ω.....±250 ppm/°C
above 2.2 MΩ.....±250 ppm/°C
TCR Tracking .....50 ppm/°C maximum; equal values
Resistor Tolerance .....See circuits
Insulation Resistance
.....10,000 megohms minimum
Dielectric Withstanding Voltage
.....200 VRMS
Operating Temperature
.....-55 °C to +125 °C

Environmental Characteristics

TESTS PER MIL-STD-202.....ΔR MAX.
Short Time Overload.....±0.25 %
Load Life.....±1.00 %
Moisture Resistance .....±0.50 %
Resistance to Soldering Heat ....±0.25 %
Terminal Strength.....±0.25 %
Thermal Shock.....±0.25 %

Physical Characteristics

Flammability .....Conforms to UL94V-0
Body Material.....Epoxy resin
Standard Packaging
.....Bulk, Ammo-pak available

How To Order

46 06 X - 101 - 222 __ LF

Model
(46 = Conformal SIP)

Number of Pins

Physical Configuration
(X = Thick Film Low Profile)

Electrical Configuration
- 101 = Bussed
- 102 = Isolated
- 104 = Dual Terminator
- AP1 = Bussed Ammo**
- AP2 = Isolated Ammo**
- AP4 = Dual Ammo**

Resistance Code
- First 2 digits are significant
- Third digit represents the number of zeros to follow.

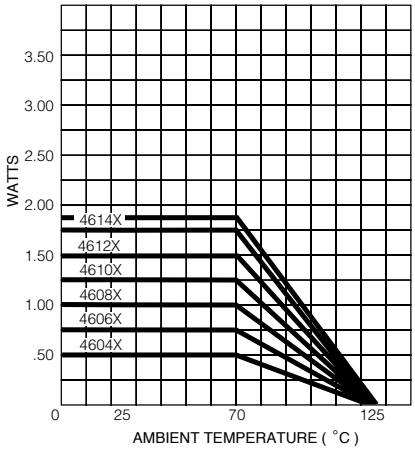
Resistance Tolerance
- Blank = ±2 % (see "Resistance Tolerance" on next page for resistance range)
- F = ±1 % (100 ohms - 5 megohms)

Terminations
- All electrical configurations EXCEPT 104 & AP4: LF = Sn/Ag/Cu-plated (RoHS compliant)
- ONLY electrical configurations 104 & AP4: L = Sn/Ag/Cu-plated (RoHS compliant)

Consult factory for other available options.

**Available for packages with 10 pins or less.

Package Power Temp. Derating Curve



Package Power Ratings (Watts)

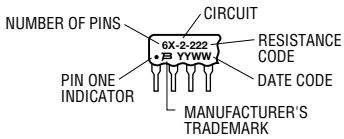
Pkg.	Ambient Temperature 70 °C	Pkg.	Ambient Temperature 70 °C
4604X	0.50	4610X	1.25
4605X	0.63	4611X	1.38
4606X	0.75	4612X	1.50
4607X	0.88	4613X	1.63
4608X	1.00	4614X	1.75
4609X	1.13		

Typical Part Marking

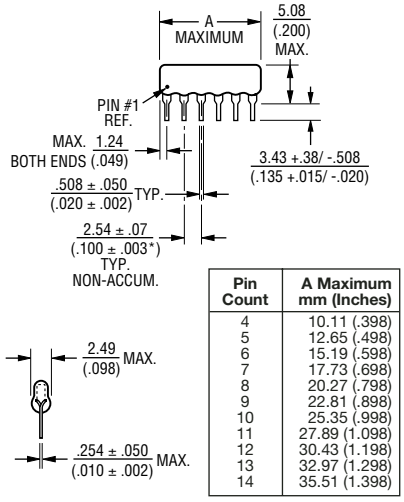
Represents total content. Layout may vary.

Part Number	Part Number
4606X-101-RC	6X-1-RC
4608X-102-RC	8X-2-RC
4610X-104-RC/RC	10X-4-RC/RC

RC = ohmic value, 3-digit resistance code.



Product Dimensions



Pin Count	A Maximum mm (Inches)
4	10.11 (.398)
5	12.65 (.498)
6	15.19 (.598)
7	17.73 (.698)
8	20.27 (.798)
9	22.81 (.898)
10	25.35 (.998)
11	27.89 (1.098)
12	30.43 (1.198)
13	32.97 (1.298)
14	35.51 (1.398)

Maximum package length is equal to 2.54mm (.100") times the number of pins, less .005mm (.002").

Governing dimensions are in metric. Dimensions in parentheses are inches and are approximate.

*Terminal centerline to centerline measurements made at point of emergence of the lead from the body.

For Standard Values Used in Capacitors, Inductors, and Resistors, click here.

For information on specific applications, download Bourns' application notes:

DRAM Applications

Dual Terminator Resistor Networks

R/2R Ladder Networks

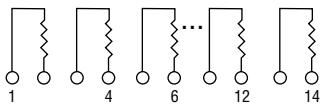
SCSI Applications

4600X Series - Thick Film Conformal SIPs

BOURNS®

Isolated Resistors (102 Circuit)

Model 4600X-102-RC
4, 6, 8, 10, 12, 14 Pin



These models incorporate 2 to 7 isolated thick-film resistors of equal value, each connected between two pins.

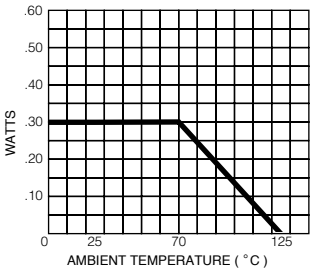
Resistance Tolerance

10 ohms to 49 ohms .....±1 ohm
50 ohms to 5 megohms.....±2 %*
Above 5 megohms.....±5 %

Power Rating per Resistor

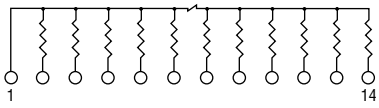
At 70 °C .....0.30 watt

Power Temperature Derating Curve



Bussed Resistors (101 Circuit)

Model 4600X-101-RC
4 through 14 Pin



These models incorporate 3 to 13 thick-film resistors of equal value, each connected between a common bus (pin 1) and a separate pin.

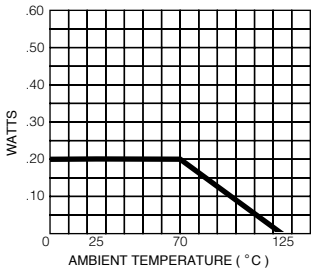
Resistance Tolerance

10 ohms to 49 ohms .....±1 ohm
50 ohms to 5 megohms.....±2 %*
Above 5 megohms.....±5 %

Power Rating per Resistor

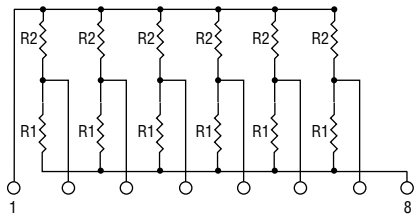
At 70 °C .....0.20 watt

Power Temperature Derating Curve



Dual Terminator (104 Circuit)

Model 4600X-104-R1/R2
4 through 14 Pin



The 4608X-104 (shown above) is an 8-pin configuration and terminates 6 lines. Pins 1 and 8 are common for ground and power, respectively. Twelve thick-film resistors are paired in series between the common lines (pins 1 and 8).

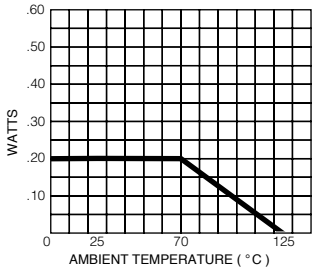
Resistance Tolerance

Below 100 ohms.....±2 ohms
100 ohms to 5 megohms.....±2 %*
Above 5 megohms.....±5 %

Power Rating per Resistor

At 70 °C .....0.20 watt

Power Temperature Derating Curve



Popular Resistance Values (101, 102 Circuits)**

Ohms	Code	Ohms	Code	Ohms	Code	Ohms	Code	Ohms	Code
10	100	180	181	1,800	182	15,000	153	120,000	124
22	220	220	221	2,000	202	18,000	183	150,000	154
27	270	270	271	2,200	222	20,000	203	180,000	184
33	330	330	331	2,700	272	22,000	223	220,000	224
39	390	390	391	3,300	332	27,000	273	270,000	274
47	470	470	471	3,900	392	33,000	333	330,000	334
56	560	560	561	4,700	472	39,000	393	390,000	394
68	680	680	681	5,600	562	47,000	473	470,000	474
82	820	820	821	6,800	682	56,000	563	560,000	564
100	101	1,000	102	8,200	822	68,000	683	680,000	684
120	121	1,200	122	10,000	103	82,000	823	820,000	824
150	151	1,500	152	12,000	123	100,000	104	1,000,000	105

Popular Resistance Values (104 Circuit)**

Resistance (Ohms)		Code	
R_1	R_2	R_1	R_2
160	240	161	241
180	390	181	391
220	270	221	271
220	330	221	331
330	390	331	391
330	470	331	471
3,000	6,200	302	622

* ±1 % TOLERANCE IS AVAILABLE BY ADDING SUFFIX CODE "F" AFTER THE RESISTANCE CODE.

**NON-STANDARD VALUES AVAILABLE, WITHIN RESISTANCE RANGE.

REV. 12/06